

## EMC 性能优异的 ISO772x 高速双通道增强型数字隔离器

### 1 特性

- 信号传输速率：高达 100Mbps
- 宽电源电压范围：2.25V 至 5.5V
- 2.25V 至 5.5V 电平转换
- 默认输出高电平和低电平选项
- 宽温度范围：-55°C 至 +125°C
- 低功耗，1Mbps 时每通道的电流典型值为 1.7mA
- 低传播延迟：典型值为 11ns（由 5V 电源供电）
- 高 CMTI：±100kV/μs（典型值）
- 优异的电磁兼容性 (EMC)
  - 系统级 ESD、EFT 和浪涌抗扰性
  - 低辐射
- 隔离栅寿命：> 40 年
- 宽体 SOIC (DW-16 和 DWV-8) 和窄体 SOIC (D-8) 封装选项
- 安全相关认证：
  - 符合 DIN V VDE V 0884-11:2017-01 标准的 VDE 增强型绝缘
  - 符合 UL 1577 的 5000V<sub>RMS</sub> (DW 和 DWV) 和 3000V<sub>RMS</sub> (D) 隔离额定值
  - 符合 IEC 60950-1、IEC 62368-1、IEC 61010-1 和 IEC 60601-1 终端设备标准的 CSA 认证
  - 符合 GB4943.1-2011 的 CQC 认证
  - 符合 EN 60950-1 和 EN 61010-1 的 TUV 认证
  - DWV 封装认证已提上日程，所有其他认证均已完成

### 2 应用

- 工业自动化
- 混合动力电动汽车
- 电机控制
- 电源
- 光伏逆变器
- 医疗设备

### 3 说明

ISO772x 器件是一款高性能双通道数字隔离器，可提供符合 UL 1577 标准的 5000V<sub>RMS</sub> (DW 和 DWV 封装) 和 3000V<sub>RMS</sub> (D 封装) 隔离额定值。这些器件还通过了 VDE、TUV、CSA 和 CQC 认证。

在隔离互补金属氧化物半导体 (CMOS) 或者低电压互补金属氧化物半导体 (LVCMOS) 数字 I/O 的同时，ISO772x 器件还可提供高电磁抗扰度和低辐射，同时具备低功耗特性。每个隔离通道都有一个由二氧化硅 (SiO<sub>2</sub>) 绝缘隔栅分开的逻辑输入和输出缓冲器。ISO7720 器件具有两条同向通道，而 ISO7721 器件具有两条反向通道。如果输入功率或信号出现损失，不带后缀 F 的器件默认输出高电平，带后缀 F 的器件默认输出低电平。更多详细信息，请参见 [器件功能模式](#) 部分。

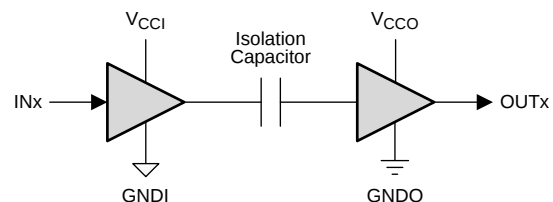
与隔离式电源一起使用时，这些器件有助于防止数据总线或者其他电路上的噪声电流进入本地接地并且干扰或损坏敏感电路。凭借创新型芯片设计和布线技术，ISO772x 器件的电磁兼容性得到了显著增强，可缓解系统级 ESD、EFT 和浪涌问题并符合辐射标准。ISO772x 系列器件可提供 16 引脚 SOIC 宽体 (DW)、8 引脚 SOIC 宽体 (DWV) 和 8 引脚 SOIC 窄体 (D) 封装。

器件信息<sup>(1)</sup>

| 器件型号                                     | 封装      | 封装尺寸 (标称值)        |
|------------------------------------------|---------|-------------------|
| ISO7720, ISO7721<br>, ISO7721F, ISO7721F | D (8)   | 4.90 mm × 3.91 mm |
|                                          | DWV (8) | 5.85mm × 7.50mm   |
|                                          | DW (16) | 10.30mm × 7.50mm  |

(1) 要了解所有可用封装，请参见数据表末尾的可订购产品附录。

简化原理图



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V<sub>CCI</sub> 和 GNDI 分别是输入通道的电源和接地连接引脚。

V<sub>CCO</sub> 和 GNDO 分别是输出通道的电源和接地连接引脚。



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## 4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

| Changes from Revision B (March 2017) to Revision C                                                                                                                                               | Page |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • 已添加 在数据表中添加了 8 引脚 SOIC 封装 (DWV) .....                                                                                                                                                          | 1    |
| • 通篇更新了 VDE 和 CSA 认证 说明 .....                                                                                                                                                                    | 1    |
| • 已更改 在特性 部分中，更改了所有需要为 DW 和 D 封装完成的认证 .....                                                                                                                                                      | 1    |
| • Changed the climatic category for the D package from 5/125/21 to 55/125/21 .....                                                                                                               | 7    |
| • Changed the maximum working voltages for DW-16 and D-8 from 400 to 700 V <sub>RMS</sub> and 250 to 400 V <sub>RMS</sub> (respectively) in the <i>Safety-Related Certifications</i> table ..... | 8    |
| • Switched the line colors for V <sub>CC</sub> at 2.5 V and V <sub>CC</sub> at 3.3 V in the <i>Low-Level Output Voltage vs Low-Level Output Current</i> graph .....                              | 15   |
| • Deleted EN from the <i>Common-Mode Transient Immunity Test Circuit</i> figure .....                                                                                                            | 17   |
| • 已添加 器件支持 部分 .....                                                                                                                                                                              | 24   |

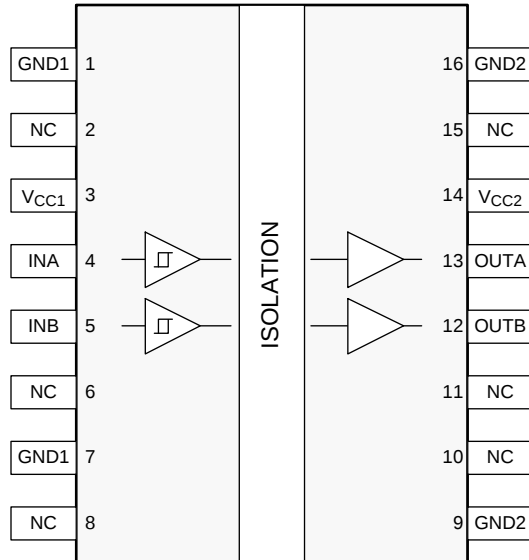
| Changes from Revision A (December 2016) to Revision B                                                            | Page |
|------------------------------------------------------------------------------------------------------------------|------|
| • Added D-8 values for TUV in the <i>Safety-Related Certifications</i> table .....                               | 8    |
| • Changed the minimum CMTI value from 40 kV/μs to 85 kV/μs in all <i>Electrical Characteristics</i> tables ..... | 10   |
| • 已添加 接收文档更新通知 部分 .....                                                                                          | 24   |
| • 已更改 静电放电注意事项 声明 .....                                                                                          | 24   |

**Changes from Original (November 2016) to Revision A**
**Page**

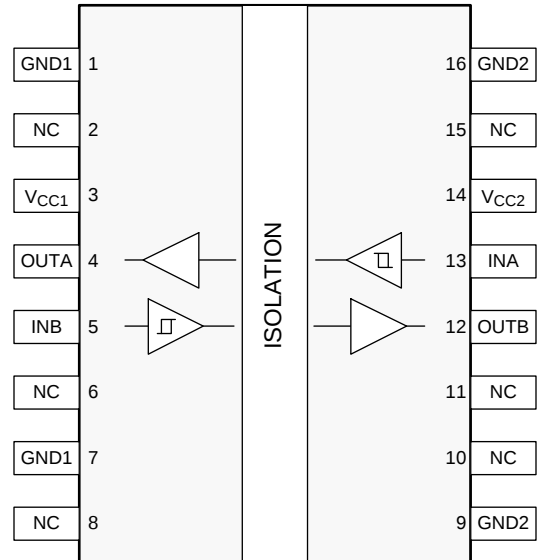
|                                                                                                    |           |
|----------------------------------------------------------------------------------------------------|-----------|
| • 将特性从“IEC 60950-1、IEC 60601-1 和 IEC 61010-1 终端设备标准”更改为“IEC 60950-1 和 IEC 60601-1 终端设备标准” .....    | <b>1</b>  |
| • Added Climatic category to the <i>Insulation Specifications</i> .....                            | <b>7</b>  |
| • Changed the CSA column of <i>Regulatory Information</i> .....                                    | <b>8</b>  |
| • Changed DW package) To: (DW-16) in the TUV column of <i>Regulatory Information</i> .....         | <b>8</b>  |
| • Changed $t_{ie}$ TYP value From: 1.5 To 1 in <i>Switching Characteristics—5-V Supply</i> .....   | <b>13</b> |
| • Changed $t_{ie}$ TYP value From: 1.5 To 1 in <i>Switching Characteristics—3.3-V Supply</i> ..... | <b>13</b> |
| • Changed $t_{ie}$ TYP value From: 1.5 To 1 in <i>Switching Characteristics—2.5-V Supply</i> ..... | <b>13</b> |

## 5 Pin Configuration and Functions

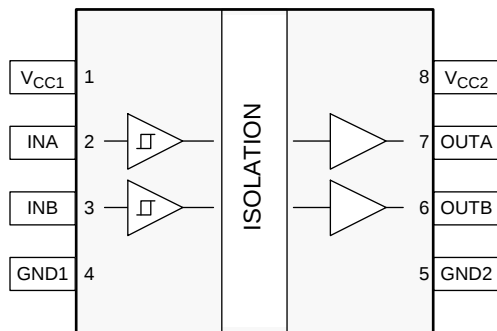
**ISO7720 DW Package  
16-Pin SOIC  
Top View**



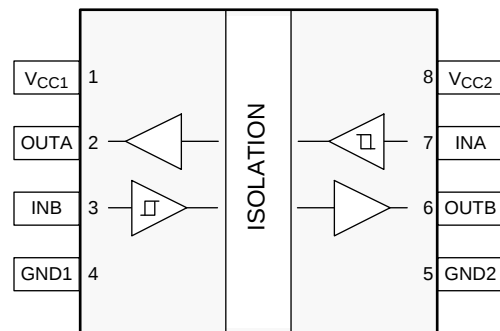
**ISO7721 DW Package  
16-Pin SOIC  
Top View**



**ISO7720 D and DWV Package  
8-Pin SOIC  
Top View**



**ISO7721 D and DWV Package  
8-Pin SOIC  
Top View**



### Pin Functions

| PIN              |                     |                     |                |         | I/O | DESCRIPTION                            |
|------------------|---------------------|---------------------|----------------|---------|-----|----------------------------------------|
| NAME             | DW PACKAGE          |                     | D, DWV PACKAGE |         |     |                                        |
|                  | ISO7720             | ISO7721             | ISO7720        | ISO7721 |     |                                        |
| GND1             | 1, 7                | 1, 7                | 4              | 4       | —   | Ground connection for V <sub>CC1</sub> |
| GND2             | 9                   | 9                   | 5              | 5       | —   | Ground connection for V <sub>CC2</sub> |
|                  | 16                  | 16                  |                |         |     |                                        |
| INA              | 4                   | 13                  | 2              | 7       | I   | Input, channel A                       |
| INB              | 5                   | 5                   | 3              | 3       | I   | Input, channel B                       |
| NC               | 2, 6, 8, 10, 11, 15 | 2, 6, 8, 10, 11, 15 | —              | —       | —   | Not connected                          |
| OUTA             | 13                  | 4                   | 7              | 2       | O   | Output, channel A                      |
| OUTB             | 12                  | 12                  | 6              | 6       | O   | Output, channel B                      |
| V <sub>CC1</sub> | 3                   | 3                   | 1              | 1       | —   | Power supply, V <sub>CC1</sub>         |
| V <sub>CC2</sub> | 14                  | 14                  | 8              | 8       | —   | Power supply, V <sub>CC2</sub>         |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

See <sup>(1)</sup>.

|                    |                               | MIN  | MAX                  | UNIT |
|--------------------|-------------------------------|------|----------------------|------|
| $V_{CC1}, V_{CC2}$ | Supply voltage <sup>(2)</sup> | −0.5 | 6                    | V    |
| V                  | Voltage at INx, OUTx          | −0.5 | $V_{CC} + 0.5^{(3)}$ | V    |
| $I_O$              | Output current                | −15  | 15                   | mA   |
| $T_J$              | Junction temperature          |      | 150                  | °C   |
| $T_{stg}$          | Storage temperature           | −65  | 150                  | °C   |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values except differential I/O bus voltages are with respect to the local ground terminal (GND1 or GND2) and are peak voltage values.
- (3) Maximum voltage must not exceed 6 V.

### 6.2 ESD Ratings

|                  |                         | VALUE                                                                                    | UNIT  |   |
|------------------|-------------------------|------------------------------------------------------------------------------------------|-------|---|
| V <sub>ESD</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>              | ±6000 | V |
|                  |                         | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±1500 | V |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

|                    |                                               | MIN                          | NOM | MAX                  | UNIT |
|--------------------|-----------------------------------------------|------------------------------|-----|----------------------|------|
| $V_{CC1}, V_{CC2}$ | Supply voltage                                | 2.25                         |     | 5.5                  | V    |
| $V_{CC(UVLO+)}$    | UVLO threshold when supply voltage is rising  |                              | 2   | 2.25                 | V    |
| $V_{CC(UVLO-)}$    | UVLO threshold when supply voltage is falling | 1.7                          | 1.8 |                      | V    |
| $V_{HYS(UVLO)}$    | Supply voltage UVLO hysteresis                | 100                          | 200 |                      | mV   |
| $I_{OH}$           | High-level output current                     | $V_{CCO}^{(1)} = 5\text{ V}$ | −4  |                      | mA   |
|                    |                                               | $V_{CCO} = 3.3\text{ V}$     | −2  |                      |      |
|                    |                                               | $V_{CCO} = 2.5\text{ V}$     | −1  |                      |      |
| $I_{OL}$           | Low-level output current                      | $V_{CCO} = 5\text{ V}$       |     | 4                    | mA   |
|                    |                                               | $V_{CCO} = 3.3\text{ V}$     |     | 2                    |      |
|                    |                                               | $V_{CCO} = 2.5\text{ V}$     |     | 1                    |      |
| $V_{IH}$           | High-level input voltage                      | $0.7 \times V_{CCI}^{(1)}$   |     | $V_{CCI}$            | V    |
| $V_{IL}$           | Low-level input voltage                       | 0                            |     | $0.3 \times V_{CCI}$ | V    |
| DR                 | Signaling rate                                | 0                            |     | 100                  | Mbps |
| $T_A$              | Ambient temperature                           | −55                          | 25  | 125                  | °C   |

- (1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | ISO772x   |            |          | UNIT |
|-------------------------------|----------------------------------------------|-----------|------------|----------|------|
|                               |                                              | DW (SOIC) | DWV (SOIC) | D (SOIC) |      |
|                               |                                              | 16 PINS   | 16 PINS    | 8 PINS   |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 86.5      | 84.3       | 137.7    | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case(top) thermal resistance     | 49.6      | 36.3       | 54.9     | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 49.7      | 47.0       | 71.7     | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 32.3      | 7.4        | 7.1      | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 49.2      | 45.1       | 70.7     | °C/W |
| R <sub>θJC(botto<br/>m)</sub> | Junction-to-case(bottom) thermal resistance  | N/A       | N/A        | N/A      | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#).

## 6.5 Power Ratings

| PARAMETER       | TEST CONDITIONS                                                                                                                                                                  | MIN | TYP | MAX | UNIT |
|-----------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| <b>ISO7720</b>  |                                                                                                                                                                                  |     |     |     |      |
| P <sub>D</sub>  | Maximum power dissipation<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave           |     |     | 100 | mW   |
| P <sub>D1</sub> | Maximum power dissipation by side-1<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave |     |     | 20  | mW   |
| P <sub>D2</sub> | Maximum power dissipation by side-2<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave |     |     | 80  | mW   |
| <b>ISO7721</b>  |                                                                                                                                                                                  |     |     |     |      |
| P <sub>D</sub>  | Maximum power dissipation<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave           |     |     | 100 | mW   |
| P <sub>D1</sub> | Maximum power dissipation by side-1<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave |     |     | 50  | mW   |
| P <sub>D2</sub> | Maximum power dissipation by side-2<br>V <sub>CC1</sub> = V <sub>CC2</sub> = 5.5 V, T <sub>J</sub> = 150°C, C <sub>L</sub> = 15 pF,<br>input a 50 MHz 50% duty cycle square wave |     |     | 50  | mW   |

## 6.6 Insulation Specifications

| PARAMETER                                  |                                                     | TEST CONDITIONS                                                                                                                                                                                                    | VALUE             |                   |                   | UNIT             |
|--------------------------------------------|-----------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-------------------|-------------------|------------------|
|                                            |                                                     |                                                                                                                                                                                                                    | DW                | DWV               | D                 |                  |
| CLR                                        | External clearance <sup>(1)</sup>                   | Shortest terminal-to-terminal distance through air                                                                                                                                                                 | 8                 | 8.5               | 4                 | mm               |
| CPG                                        | External creepage <sup>(1)</sup>                    | Shortest terminal-to-terminal distance across the package surface                                                                                                                                                  | 8                 | 8.5               | 4                 | mm               |
| DTI                                        | Distance through the insulation                     | Minimum internal gap (internal clearance)                                                                                                                                                                          | 21                | 21                | 21                | μm               |
| CTI                                        | Comparative tracking index                          | DIN EN 60112 (VDE 0303-11); IEC 60112; UL 746A                                                                                                                                                                     | >600              | >600              | >600              | V                |
|                                            | Material group                                      | According to IEC 60664-1                                                                                                                                                                                           | I                 | I                 | I                 |                  |
|                                            | Overvoltage category per IEC 60664-1                | Rated mains voltage ≤ 150 V <sub>RMS</sub>                                                                                                                                                                         | I–IV              | I–IV              | I–IV              |                  |
|                                            |                                                     | Rated mains voltage ≤ 300 V <sub>RMS</sub>                                                                                                                                                                         | I–IV              | I–IV              | I–III             |                  |
|                                            |                                                     | Rated mains voltage ≤ 600 V <sub>RMS</sub>                                                                                                                                                                         | I–IV              | I–IV              | n/a               |                  |
|                                            |                                                     | Rated mains voltage ≤ 1000 V <sub>RMS</sub>                                                                                                                                                                        | I–III             | I–III             | n/a               |                  |
| DIN V VDE V 0884-11:2017-01 <sup>(2)</sup> |                                                     |                                                                                                                                                                                                                    |                   |                   |                   |                  |
| V <sub>IORM</sub>                          | Maximum repetitive peak isolation voltage           | AC voltage (bipolar)                                                                                                                                                                                               | 1414              | 1414              | 637               | V <sub>PK</sub>  |
| V <sub>IOWM</sub>                          | Maximum working isolation voltage                   | AC voltage; Time dependent dielectric breakdown (TDDB) test                                                                                                                                                        | 1000              | 1000              | 450               | V <sub>RMS</sub> |
|                                            |                                                     | DC voltage                                                                                                                                                                                                         | 1414              | 1414              | 637               | V <sub>DC</sub>  |
| V <sub>IOTM</sub>                          | Maximum transient isolation voltage                 | V <sub>TEST</sub> = V <sub>IOTM</sub> , t = 60 s (qualification); t = 1 s (100% production)                                                                                                                        | 8000              | 7071              | 4242              | V <sub>PK</sub>  |
| V <sub>IOSM</sub>                          | Maximum surge isolation voltage <sup>(3)</sup>      | Test method per IEC 60065, 1.2/50 μs waveform, V <sub>TEST</sub> = 1.6 × V <sub>IOSM</sub> (qualification)                                                                                                         | 8000              | 8000              | 5000              | V <sub>PK</sub>  |
| q <sub>pd</sub>                            | Apparent charge <sup>(4)</sup>                      | Method a, After Input/Output safety test subgroup 2/3, V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s; V <sub>pd(m)</sub> = 1.2 × V <sub>IORM</sub> , t <sub>m</sub> = 10 s                        | ≤5                | ≤5                | ≤5                | pC               |
|                                            |                                                     | Method a, After environmental tests subgroup 1, V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 60 s; V <sub>pd(m)</sub> = 1.6 × V <sub>IORM</sub> , t <sub>m</sub> = 10 s                               | ≤5                | ≤5                | ≤5                |                  |
|                                            |                                                     | Method b1; At routine test (100% production) and preconditioning (type test), V <sub>ini</sub> = V <sub>IOTM</sub> , t <sub>ini</sub> = 1 s; V <sub>pd(m)</sub> = 1.875 × V <sub>IORM</sub> , t <sub>m</sub> = 1 s | ≤5                | ≤5                | ≤5                |                  |
| C <sub>IO</sub>                            | Barrier capacitance, input to output <sup>(5)</sup> | V <sub>IO</sub> = 0.4 × sin (2πft), f = 1 MHz                                                                                                                                                                      | ~0.5              | ~0.5              | ~0.5              | pF               |
| R <sub>IO</sub>                            | Isolation resistance <sup>(5)</sup>                 | V <sub>IO</sub> = 500 V, T <sub>A</sub> = 25°C                                                                                                                                                                     | >10 <sup>12</sup> | >10 <sup>12</sup> | >10 <sup>12</sup> | Ω                |
|                                            |                                                     | V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ 125°C                                                                                                                                                            | >10 <sup>11</sup> | >10 <sup>11</sup> | >10 <sup>11</sup> |                  |
|                                            |                                                     | V <sub>IO</sub> = 500 V at T <sub>S</sub> = 150°C                                                                                                                                                                  | >10 <sup>9</sup>  | >10 <sup>9</sup>  | >10 <sup>9</sup>  |                  |
|                                            | Pollution degree                                    |                                                                                                                                                                                                                    | 2                 | 2                 | 2                 |                  |
|                                            | Climatic category                                   |                                                                                                                                                                                                                    | 55/125/21         | 55/125/21         | 55/125/21         |                  |
| UL 1577                                    |                                                     |                                                                                                                                                                                                                    |                   |                   |                   |                  |
| V <sub>ISO</sub>                           | Withstanding isolation voltage                      | V <sub>TEST</sub> = V <sub>ISO</sub> , t = 60 s(qualification); V <sub>TEST</sub> = 1.2 × V <sub>ISO</sub> , t = 1 s (100% production)                                                                             | 5000              | 5000              | 3000              | V <sub>RMS</sub> |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed-circuit board do not reduce this distance. Creepage and clearance on a printed-circuit board become equal in certain cases. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.
- (2) This coupler is suitable for *safe electrical insulation* only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.
- (3) Testing is carried out in air or oil to determine the intrinsic surge immunity of the isolation barrier.
- (4) Apparent charge is electrical discharge caused by a partial discharge (pd).
- (5) All pins on each side of the barrier tied together creating a two-terminal device.

## 6.7 Safety-Related Certifications

DWV package certifications are planned; all other certifications are complete.

| VDE                                                                                                                                                                                                                                                                                                                                             | CSA                                                                                                                                                                                                                                                                                                                                      | UL                                                                                                               | CQC                                                                                                                                                                                                                                        | TUV                                                                                                                                                                                                                                                                                                                                                                                                                                               |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Certified according to DIN V VDE V 0884-11:2017-01                                                                                                                                                                                                                                                                                              | Certified according to IEC 60950-1, IEC 62368-1, IEC 61010-1, and IEC 60601-1                                                                                                                                                                                                                                                            | Certified according to UL 1577 Component Recognition Program                                                     | Certified according to GB4943.1-2011                                                                                                                                                                                                       | Certified according to EN 61010-1:2010 (3rd Ed) and EN 60950-1:2006/A11:2009/A1:2010/A12:2011/A2:2013                                                                                                                                                                                                                                                                                                                                             |
| Maximum transient isolation voltage, 8000 V <sub>PK</sub> (DW-16, Reinforced) and 4242 V <sub>PK</sub> (D-8);<br>Maximum repetitive peak isolation voltage, 1414 V <sub>PK</sub> (DW-16, Reinforced) and 637 V <sub>PK</sub> (D-8);<br>Maximum surge isolation voltage, 8000 V <sub>PK</sub> (DW-16, Reinforced) and 5000 V <sub>PK</sub> (D-8) | Reinforced insulation per CSA 60950-1-07+A1+A2 and IEC 60950-1 2nd Ed., 800 V <sub>RMS</sub> (DW-16) and 400 V <sub>RMS</sub> (D-8) max working voltage (pollution degree 2, material group I);<br><br>2 MOPP (Means of Patient Protection) per CSA 60601-1:14 and IEC 60601-1 Ed. 3.1, 250 V <sub>RMS</sub> (DW-16) max working voltage | <b>DW-16:</b> Single protection, 5000 V <sub>RMS</sub> ;<br><b>D-8:</b> Single protection, 3000 V <sub>RMS</sub> | <b>DW-16:</b> Reinforced Insulation, Altitude ≤ 5000 m, Tropical Climate, 700 V <sub>RMS</sub> maximum working voltage;<br><b>D-8:</b> Basic Insulation, Altitude ≤ 5000 m, Tropical Climate, 400 V <sub>RMS</sub> maximum working voltage | 5000 V <sub>RMS</sub> (DW-16) and 3000 V <sub>RMS</sub> (D-8)<br>Reinforced insulation per EN 61010-1:2010 (3rd Ed) up to working voltage of 600 V <sub>RMS</sub> (DW-16) and 300 V <sub>RMS</sub> (D-8)<br><br>5000 V <sub>RMS</sub> (DW-16) and 3000 V <sub>RMS</sub> (D-8)<br>Reinforced insulation per EN 60950-1:2006/A11:2009/A1:2010/A12:2011/A2:2013 up to working voltage of 800 V <sub>RMS</sub> (DW-16) and 400 V <sub>RMS</sub> (D-8) |
| Certificate number: 40040142                                                                                                                                                                                                                                                                                                                    | Master contract number: 220991                                                                                                                                                                                                                                                                                                           | File number: E181974                                                                                             | Certificate number: CQC15001121716 (DW-16), CQC15001121656 (D-8)                                                                                                                                                                           | Client ID number: 77311                                                                                                                                                                                                                                                                                                                                                                                                                           |

## 6.8 Safety Limiting Values

Safety limiting intends to minimize potential damage to the isolation barrier upon failure of input or output circuitry.

| PARAMETER            |                                                        | TEST CONDITIONS                                                                                                                     | MIN | TYP | MAX  | UNIT |
|----------------------|--------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------|-----|-----|------|------|
| <b>DW-16 PACKAGE</b> |                                                        |                                                                                                                                     |     |     |      |      |
| I <sub>S</sub>       | Safety input, output, or supply current <sup>(1)</sup> | R <sub>θJA</sub> = 86.5 °C/W, V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 1</a>   |     |     | 263  | mA   |
|                      |                                                        | R <sub>θJA</sub> = 86.5 °C/W, V <sub>I</sub> = 3.6 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 1</a>   |     |     | 401  |      |
|                      |                                                        | R <sub>θJA</sub> = 86.5 °C/W, V <sub>I</sub> = 2.75 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 1</a>  |     |     | 525  |      |
| P <sub>S</sub>       | Safety input, output, or total power <sup>(1)</sup>    | R <sub>θJA</sub> = 86.5 °C/W, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 2</a>                           |     |     | 1445 | mW   |
| T <sub>S</sub>       | Maximum safety temperature <sup>(1)</sup>              |                                                                                                                                     |     |     | 150  | °C   |
| <b>DWV-8 PACKAGE</b> |                                                        |                                                                                                                                     |     |     |      |      |
| I <sub>S</sub>       | Safety input, output, or supply current <sup>(1)</sup> | R <sub>θJA</sub> = 84.3 °C/W, V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 3</a>   |     |     | 270  | mA   |
|                      |                                                        | R <sub>θJA</sub> = 84.3 °C/W, V <sub>I</sub> = 3.6 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 3</a>   |     |     | 412  |      |
|                      |                                                        | R <sub>θJA</sub> = 84.3 °C/W, V <sub>I</sub> = 2.75 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 3</a>  |     |     | 539  |      |
| P <sub>S</sub>       | Safety input, output, or total power <sup>(1)</sup>    | R <sub>θJA</sub> = 84.3 °C/W, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 4</a>                           |     |     | 1483 | mW   |
| T <sub>S</sub>       | Maximum safety temperature <sup>(1)</sup>              |                                                                                                                                     |     |     | 150  | °C   |
| <b>D-8 PACKAGE</b>   |                                                        |                                                                                                                                     |     |     |      |      |
| I <sub>S</sub>       | Safety input, output, or supply current <sup>(1)</sup> | R <sub>θJA</sub> = 137.7 °C/W, V <sub>I</sub> = 5.5 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 5</a>  |     |     | 165  | mA   |
|                      |                                                        | R <sub>θJA</sub> = 137.7 °C/W, V <sub>I</sub> = 3.6 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 5</a>  |     |     | 252  |      |
|                      |                                                        | R <sub>θJA</sub> = 137.7 °C/W, V <sub>I</sub> = 2.75 V, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 5</a> |     |     | 330  |      |
| P <sub>S</sub>       | Safety input, output, or total power <sup>(1)</sup>    | R <sub>θJA</sub> = 137.7 °C/W, T <sub>J</sub> = 150°C, T <sub>A</sub> = 25°C, see <a href="#">Figure 6</a>                          |     |     | 908  | mW   |
| T <sub>S</sub>       | Maximum safety temperature <sup>(1)</sup>              |                                                                                                                                     |     |     | 150  | °C   |

- (1) The maximum safety temperature, T<sub>S</sub>, has the same value as the maximum junction temperature, T<sub>J</sub>, specified for the device. The I<sub>S</sub> and P<sub>S</sub> parameters represent the safety current and safety power respectively. The maximum limits of I<sub>S</sub> and P<sub>S</sub> should not be exceeded. These limits vary with the ambient temperature, T<sub>A</sub>.

The junction-to-air thermal resistance, R<sub>θJA</sub>, in the [Thermal Information](#) table is that of a device installed on a high-K test board for leaded surface-mount packages. Use these equations to calculate the value for each parameter:

$T_J = T_A + R_{\theta JA} \times P$ , where P is the power dissipated in the device.

$T_{J(max)} = T_S = T_A + R_{\theta JA} \times P_S$ , where T<sub>J(max)</sub> is the maximum allowed junction temperature.

$P_S = I_S \times V_I$ , where V<sub>I</sub> is the maximum input voltage.

## 6.9 Electrical Characteristics—5-V Supply

 $V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                       | TEST CONDITIONS                                                                          | MIN                   | TYP                  | MAX                  | UNIT                    |
|-------------------------------------------------|------------------------------------------------------------------------------------------|-----------------------|----------------------|----------------------|-------------------------|
| $V_{OH}$ High-level output voltage              | $I_{OH} = -4\text{ mA}$ ; see Figure 15                                                  | $V_{CCO}^{(1)} - 0.4$ | 4.8                  |                      | V                       |
| $V_{OL}$ Low-level output voltage               | $I_{OL} = 4\text{ mA}$ ; see Figure 15                                                   |                       | 0.2                  | 0.4                  | V                       |
| $V_{IT+(IN)}$ Rising input threshold voltage    |                                                                                          |                       | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ | V                       |
| $V_{IT-(IN)}$ Falling input threshold voltage   |                                                                                          | $0.3 \times V_{CCI}$  | $0.4 \times V_{CCI}$ |                      | V                       |
| $V_{I(HYS)}$ Input threshold voltage hysteresis |                                                                                          | $0.1 \times V_{CCI}$  | $0.2 \times V_{CCI}$ |                      | V                       |
| $I_{IH}$ High-level input current               | $V_{IH} = V_{CCI}^{(1)}$ at INx                                                          |                       |                      | 10                   | $\mu\text{A}$           |
| $I_{IL}$ Low-level input current                | $V_{IL} = 0\text{ V}$ at INx                                                             | -10                   |                      |                      | $\mu\text{A}$           |
| CMTI Common-mode transient immunity             | $V_I = V_{CCI}$ or $0\text{ V}$ , $V_{CM} = 1200\text{ V}$ ; see Figure 17               | 85                    | 100                  |                      | $\text{kV}/\mu\text{s}$ |
| $C_i$ Input Capacitance <sup>(2)</sup>          | $V_I = V_{CC}/2 + 0.4 \times \sin(2\pi ft)$ , $f = 1\text{ MHz}$ , $V_{CC} = 5\text{ V}$ |                       | 2                    |                      | pF                      |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

(2) Measured from input pin to ground.

## 6.10 Supply Current Characteristics—5-V Supply

 $V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS                                                           |  | SUPPLY CURRENT     | MIN | TYP                | MAX | UNIT |     |     |
|----------------------------|---------------------------------------------------------------------------|--|--------------------|-----|--------------------|-----|------|-----|-----|
| ISO7720                    |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7720), $V_I = 0\text{ V}$ (ISO7720 with F suffix)     |  | $I_{CC1}$          |     | 0.8                | 1.1 | mA   |     |     |
|                            |                                                                           |  | $I_{CC2}$          |     | 1.1                | 1.7 |      |     |     |
|                            | $V_I = 0\text{ V}$ (ISO7720), $V_I = V_{CCI}$ (ISO7720 with F suffix)     |  | $I_{CC1}$          |     | 2.9                | 4.2 |      |     |     |
|                            |                                                                           |  | $I_{CC2}$          |     | 1.2                | 1.9 |      |     |     |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ |  | 1 Mbps             |     | $I_{CC1}$          |     |      | 1.8 | 2.7 |
|                            |                                                                           |  |                    |     | $I_{CC2}$          |     |      | 1.3 | 1.9 |
|                            |                                                                           |  | 10 Mbps            |     | $I_{CC1}$          |     |      | 1.9 | 2.7 |
|                            |                                                                           |  |                    |     | $I_{CC2}$          |     |      | 2.2 | 3   |
|                            |                                                                           |  | 100 Mbps           |     | $I_{CC1}$          |     | 2.5  | 3.2 |     |
|                            |                                                                           |  |                    |     | $I_{CC2}$          |     | 11.6 | 14  |     |
| ISO7721                    |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7721),<br>$V_I = 0\text{ V}$ (ISO7721 with F suffix)  |  | $I_{CC1}, I_{CC2}$ |     | 1                  |     | 1.6  | mA  |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ |  | $I_{CC1}, I_{CC2}$ |     | 2.2                |     | 3.2  |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ |  | 1 Mbps             |     | $I_{CC1}, I_{CC2}$ |     | 1.7  | 2.4 |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ |  | 10 Mbps            |     | $I_{CC1}, I_{CC2}$ |     | 2.2  | 3   |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ |  | 100 Mbps           |     | $I_{CC1}, I_{CC2}$ |     | 7.3  | 9   |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |
|                            |                                                                           |  |                    |     |                    |     |      |     |     |

## 6.11 Electrical Characteristics—3.3-V Supply

 $V_{CC1} = V_{CC2} = 3.3 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER     | TEST CONDITIONS                                                                                                                | MIN                   | TYP                  | MAX                  | UNIT              |
|---------------|--------------------------------------------------------------------------------------------------------------------------------|-----------------------|----------------------|----------------------|-------------------|
| $V_{OH}$      | High-level output voltage<br>$I_{OH} = -2 \text{ mA}$ ; see <a href="#">Figure 15</a>                                          | $V_{CCO}^{(1)} - 0.3$ | 3.2                  |                      | V                 |
| $V_{OL}$      | Low-level output voltage<br>$I_{OL} = 2 \text{ mA}$ ; see <a href="#">Figure 15</a>                                            |                       | 0.1                  | 0.3                  | V                 |
| $V_{IT+(IN)}$ | Rising input voltage threshold                                                                                                 |                       | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ | V                 |
| $V_{IT-(IN)}$ | Falling input voltage threshold                                                                                                | $0.3 \times V_{CCI}$  | $0.4 \times V_{CCI}$ |                      | V                 |
| $V_{I(HYS)}$  | Input threshold voltage hysteresis                                                                                             | $0.1 \times V_{CCI}$  | $0.2 \times V_{CCI}$ |                      | V                 |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}^{(1)}$ at $INx$                                                                  |                       |                      | 10                   | $\mu\text{A}$     |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at $INx$                                                                     | -10                   |                      |                      | $\mu\text{A}$     |
| CMTI          | Common-mode transient immunity<br>$V_I = V_{CCI}$ or $0 \text{ V}$ , $V_{CM} = 1200 \text{ V}$ ; see <a href="#">Figure 17</a> | 85                    | 100                  |                      | kV/ $\mu\text{s}$ |

(1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 6.12 Supply Current Characteristics—3.3-V Supply

 $V_{CC1} = V_{CC2} = 3.3 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS                                                           |          | SUPPLY CURRENT     | MIN | TYP | MAX | UNIT |
|----------------------------|---------------------------------------------------------------------------|----------|--------------------|-----|-----|-----|------|
| ISO7720                    |                                                                           |          |                    |     |     |     |      |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7720), $V_I = 0\text{ V}$ (ISO7720 with F suffix)     |          | $I_{CC1}$          |     | 0.8 | 1.1 | mA   |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.1 | 1.7 |      |
|                            | $V_I = 0\text{ V}$ (ISO7720), $V_I = V_{CCI}$ (ISO7720 with F suffix)     |          | $I_{CC1}$          |     | 2.9 | 4.2 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.2 | 1.9 |      |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ | 1 Mbps   | $I_{CC1}$          |     | 1.8 | 2.7 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.2 | 1.9 |      |
|                            |                                                                           | 10 Mbps  | $I_{CC1}$          |     | 1.9 | 2.7 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.9 | 2.6 |      |
|                            |                                                                           | 100 Mbps | $I_{CC1}$          |     | 2.2 | 3.1 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 8.6 | 11  |      |
| ISO7721                    |                                                                           |          |                    |     |     |     |      |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7721), $V_I = 0\text{ V}$ (ISO7721 with F suffix)     |          | $I_{CC1}, I_{CC2}$ |     | 1   | 1.6 | mA   |
|                            | $V_I = 0\text{ V}$ (ISO7721), $V_I = V_{CCI}$ (ISO7721 with F suffix)     |          | $I_{CC1}, I_{CC2}$ |     | 2.2 | 3.2 |      |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ | 1 Mbps   | $I_{CC1}, I_{CC2}$ |     | 1.6 | 2.4 |      |
|                            |                                                                           | 10 Mbps  | $I_{CC1}, I_{CC2}$ |     | 2   | 2.8 |      |
|                            |                                                                           | 100 Mbps | $I_{CC1}, I_{CC2}$ |     | 5.6 | 7   |      |

## 6.13 Electrical Characteristics—2.5-V Supply

 $V_{CC1} = V_{CC2} = 2.5 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER     | TEST CONDITIONS                                                                                                                | MIN                   | TYP                  | MAX                  | UNIT                    |
|---------------|--------------------------------------------------------------------------------------------------------------------------------|-----------------------|----------------------|----------------------|-------------------------|
| $V_{OH}$      | High-level output voltage<br>$I_{OH} = -1 \text{ mA}$ ; see <a href="#">Figure 15</a>                                          | $V_{CCO}^{(1)} - 0.2$ | 2.45                 |                      | V                       |
| $V_{OL}$      | Low-level output voltage<br>$I_{OL} = 1 \text{ mA}$ ; see <a href="#">Figure 15</a>                                            |                       | 0.05                 | 0.2                  | V                       |
| $V_{IT+(IN)}$ | Rising input voltage threshold                                                                                                 |                       | $0.6 \times V_{CCI}$ | $0.7 \times V_{CCI}$ | V                       |
| $V_{IT-(IN)}$ | Falling input voltage threshold                                                                                                | $0.3 \times V_{CCI}$  | $0.4 \times V_{CCI}$ |                      | V                       |
| $V_{I(HYS)}$  | Input threshold voltage hysteresis                                                                                             | $0.1 \times V_{CCI}$  | $0.2 \times V_{CCI}$ |                      | V                       |
| $I_{IH}$      | High-level input current<br>$V_{IH} = V_{CCI}^{(1)}$ at $INx$                                                                  |                       |                      | 10                   | $\mu\text{A}$           |
| $I_{IL}$      | Low-level input current<br>$V_{IL} = 0 \text{ V}$ at $INx$                                                                     | -10                   |                      |                      | $\mu\text{A}$           |
| CMTI          | Common-mode transient immunity<br>$V_I = V_{CCI}$ or $0 \text{ V}$ , $V_{CM} = 1200 \text{ V}$ ; see <a href="#">Figure 17</a> | 85                    | 100                  |                      | $\text{kV}/\mu\text{s}$ |

 (1)  $V_{CCI}$  = Input-side  $V_{CC}$ ;  $V_{CCO}$  = Output-side  $V_{CC}$ .

## 6.14 Supply Current Characteristics—2.5-V Supply

 $V_{CC1} = V_{CC2} = 2.5 \text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                  | TEST CONDITIONS                                                           |          | SUPPLY CURRENT     | MIN | TYP | MAX | UNIT |
|----------------------------|---------------------------------------------------------------------------|----------|--------------------|-----|-----|-----|------|
| ISO7720                    |                                                                           |          |                    |     |     |     |      |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7720), $V_I = 0\text{ V}$ (ISO7720 with F suffix)     |          | $I_{CC1}$          |     | 0.8 | 1.1 | mA   |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.1 | 1.7 |      |
|                            | $V_I = 0\text{ V}$ (ISO7720), $V_I = V_{CCI}$ (ISO7720 with F suffix)     |          | $I_{CC1}$          |     | 2.9 | 4.2 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.2 | 1.9 |      |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ | 1 Mbps   | $I_{CC1}$          |     | 1.8 | 2.7 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.3 | 1.9 |      |
|                            |                                                                           | 10 Mbps  | $I_{CC1}$          |     | 1.9 | 2.7 |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 1.7 | 2.4 |      |
|                            |                                                                           | 100 Mbps | $I_{CC1}$          |     | 2.2 | 3   |      |
|                            |                                                                           |          | $I_{CC2}$          |     | 6.8 | 9   |      |
| ISO7721                    |                                                                           |          |                    |     |     |     |      |
| Supply current - DC signal | $V_I = V_{CCI}$ (ISO7721), $V_I = 0\text{ V}$ (ISO7721 with F suffix)     |          | $I_{CC1}, I_{CC2}$ |     | 1   | 1.6 | mA   |
|                            | $V_I = 0\text{ V}$ (ISO7721), $V_I = V_{CCI}$ (ISO7721 with F suffix)     |          | $I_{CC1}, I_{CC2}$ |     | 2.2 | 3.2 |      |
| Supply current - AC signal | All channels switching with square wave clock input; $C_L = 15\text{ pF}$ | 1 Mbps   | $I_{CC1}, I_{CC2}$ |     | 1.6 | 2.4 |      |
|                            |                                                                           | 10 Mbps  | $I_{CC1}, I_{CC2}$ |     | 1.9 | 2.7 |      |
|                            |                                                                           | 100 Mbps | $I_{CC1}, I_{CC2}$ |     | 4.6 | 6   |      |

## 6.15 Switching Characteristics—5-V Supply

 $V_{CC1} = V_{CC2} = 5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                       | TEST CONDITIONS                                                 | MIN | TYP | MAX | UNIT    |
|-----------------------------------------------------------------|-----------------------------------------------------------------|-----|-----|-----|---------|
| $t_{PLH}$ , $t_{PHL}$ Propagation delay time                    | See Figure 15                                                   | 6   | 11  | 16  | ns      |
| PWD Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ |                                                                 |     | 0.5 | 4.9 | ns      |
| $t_{sk(o)}$ Channel-to-channel output skew time <sup>(2)</sup>  | Same direction channels                                         |     |     | 4   | ns      |
| $t_{sk(pp)}$ Part-to-part skew time <sup>(3)</sup>              |                                                                 |     |     | 4.5 | ns      |
| $t_r$ Output signal rise time                                   | See Figure 15                                                   |     | 1.8 | 3.9 | ns      |
| $t_f$ Output signal fall time                                   |                                                                 |     | 1.9 | 3.9 | ns      |
| $t_{DO}$ Default output delay time from input power loss        | Measured from the time $V_{CC}$ goes below 1.7 V. See Figure 16 |     | 0.1 | 0.3 | $\mu$ s |
| $t_{ie}$ Time interval error                                    | $2^{16} - 1$ PRBS data at 100 Mbps                              |     | 1   |     | ns      |

- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.16 Switching Characteristics—3.3-V Supply

 $V_{CC1} = V_{CC2} = 3.3\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                       | TEST CONDITIONS                                                 | MIN | TYP | MAX | UNIT    |
|-----------------------------------------------------------------|-----------------------------------------------------------------|-----|-----|-----|---------|
| $t_{PLH}$ , $t_{PHL}$ Propagation delay time                    | See Figure 15                                                   | 6   | 11  | 16  | ns      |
| PWD Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ |                                                                 |     | 0.5 | 5   | ns      |
| $t_{sk(o)}$ Channel-to-channel output skew time <sup>(2)</sup>  | Same direction channels                                         |     |     | 4.1 | ns      |
| $t_{sk(pp)}$ Part-to-part skew time <sup>(3)</sup>              |                                                                 |     |     | 4.5 | ns      |
| $t_r$ Output signal rise time                                   | See Figure 15                                                   |     | 0.7 | 3   | ns      |
| $t_f$ Output signal fall time                                   |                                                                 |     | 0.7 | 3   | ns      |
| $t_{DO}$ Default output delay time from input power loss        | Measured from the time $V_{CC}$ goes below 1.7 V. See Figure 16 |     | 0.1 | 0.3 | $\mu$ s |
| $t_{ie}$ Time interval error                                    | $2^{16} - 1$ PRBS data at 100 Mbps                              |     | 1   |     | ns      |

- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.17 Switching Characteristics—2.5-V Supply

 $V_{CC1} = V_{CC2} = 2.5\text{ V} \pm 10\%$  (over recommended operating conditions unless otherwise noted)

| PARAMETER                                                       | TEST CONDITIONS                                                 | MIN | TYP | MAX  | UNIT    |
|-----------------------------------------------------------------|-----------------------------------------------------------------|-----|-----|------|---------|
| $t_{PLH}$ , $t_{PHL}$ Propagation delay time                    | See Figure 15                                                   | 7.5 | 12  | 18.5 | ns      |
| PWD Pulse width distortion <sup>(1)</sup> $ t_{PHL} - t_{PLH} $ |                                                                 |     | 0.5 | 5.1  | ns      |
| $t_{sk(o)}$ Channel-to-channel output skew time <sup>(2)</sup>  | Same direction channels                                         |     |     | 4.1  | ns      |
| $t_{sk(pp)}$ Part-to-part skew time <sup>(3)</sup>              |                                                                 |     |     | 4.6  | ns      |
| $t_r$ Output signal rise time                                   | See Figure 15                                                   |     | 1   | 3.5  | ns      |
| $t_f$ Output signal fall time                                   |                                                                 |     | 1   | 3.5  | ns      |
| $t_{DO}$ Default output delay time from input power loss        | Measured from the time $V_{CC}$ goes below 1.7 V. See Figure 16 |     | 0.1 | 0.3  | $\mu$ s |
| $t_{ie}$ Time interval error                                    | $2^{16} - 1$ PRBS data at 100 Mbps                              |     | 1   |      | ns      |

- (1) Also known as pulse skew.
- (2)  $t_{sk(o)}$  is the skew between outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical loads.
- (3)  $t_{sk(pp)}$  is the magnitude of the difference in propagation delay times between any terminals of different devices switching in the same direction while operating at identical supply voltages, temperature, input signals and loads.

## 6.18 Insulation Characteristics Curves

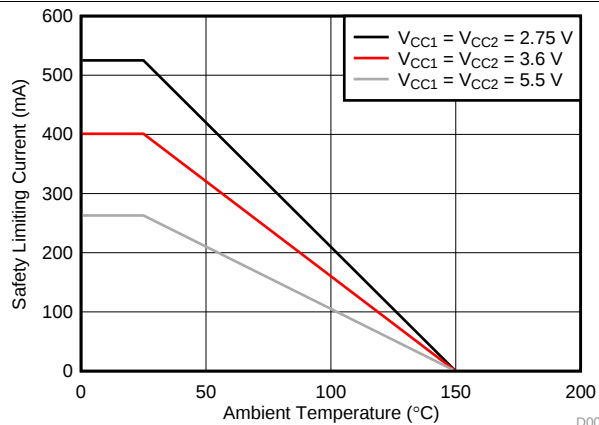


Figure 1. Thermal Derating Curve for Limiting Current per VDE for DW-16 Package

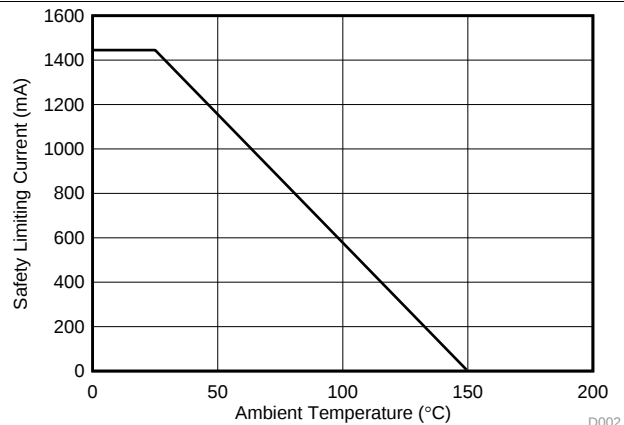


Figure 2. Thermal Derating Curve for Limiting Power per VDE for DW-16 Package

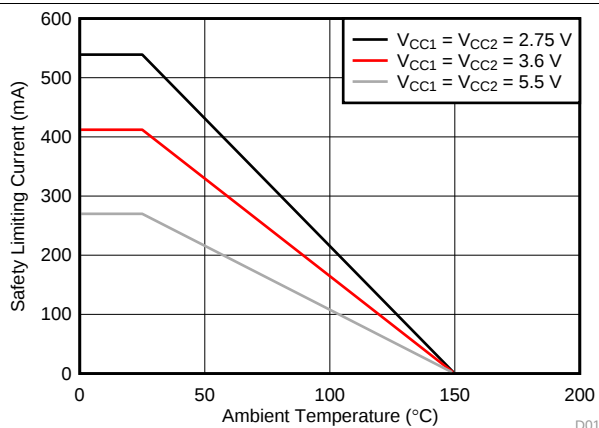


Figure 3. Thermal Derating Curve for Limiting Current per VDE for DWV-8 Package

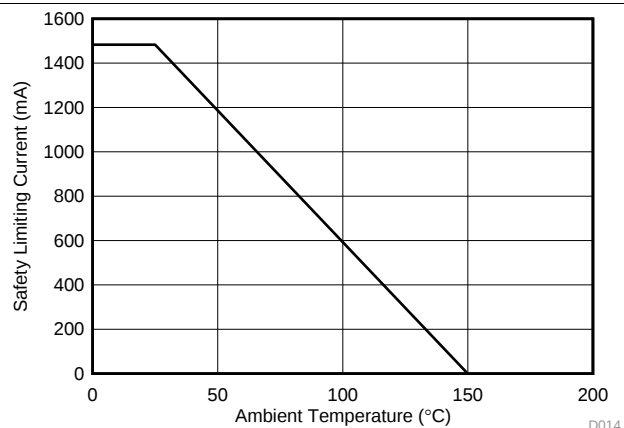


Figure 4. Thermal Derating Curve for Limiting Power per VDE for DWV-8 Package

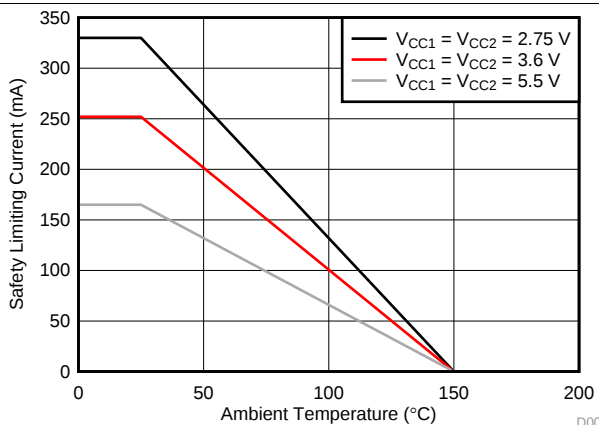


Figure 5. Thermal Derating Curve for Limiting Current per VDE for D-8 Package

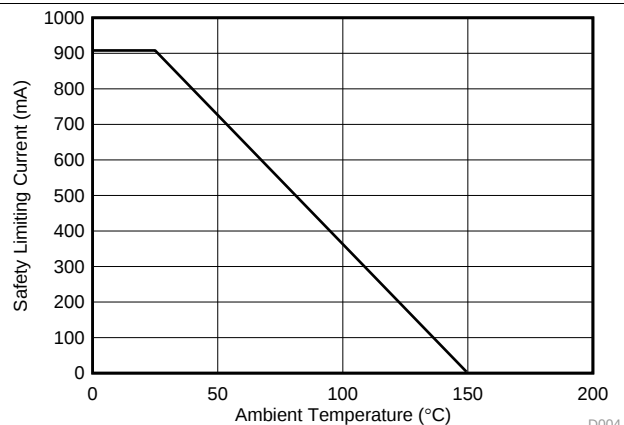
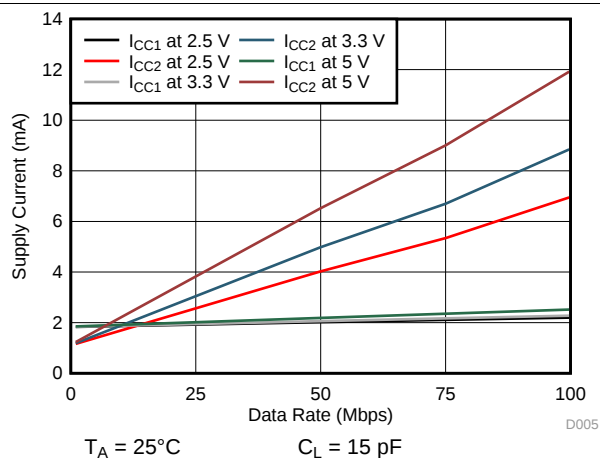
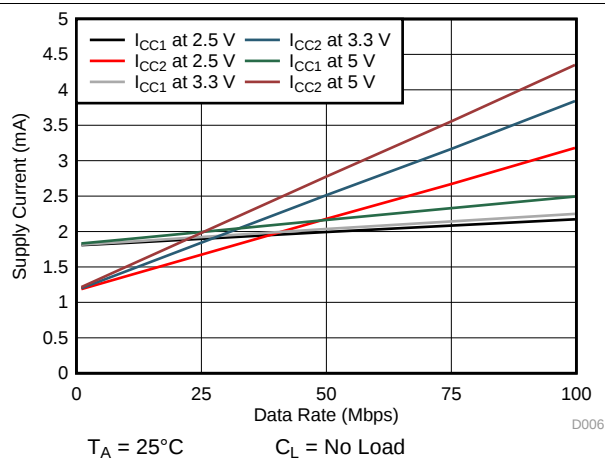


Figure 6. Thermal Derating Curve for Limiting Power per VDE for D-8 Package

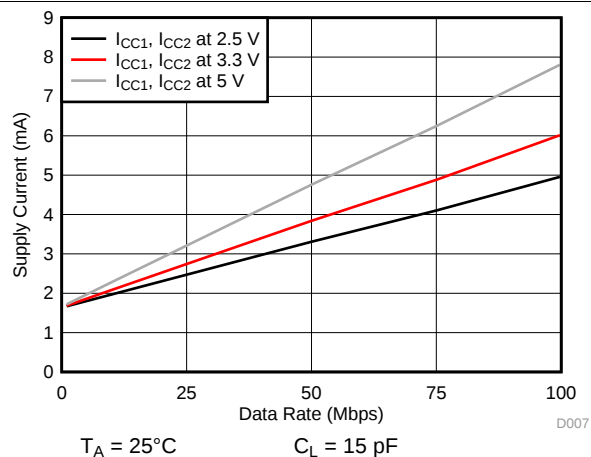
## 6.19 Typical Characteristics



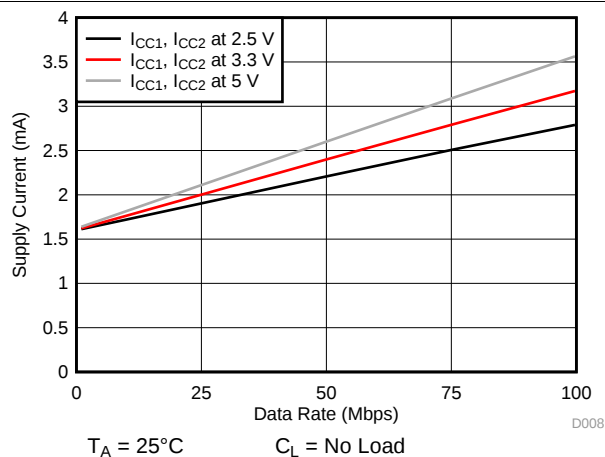
**Figure 7. ISO7720 Supply Current vs Data Rate (With 15-pF Load)**



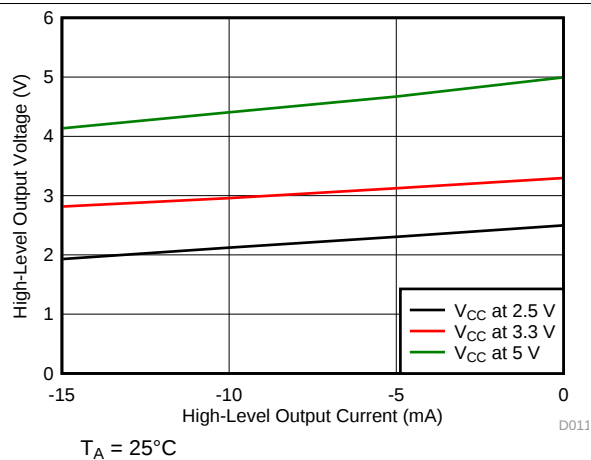
**Figure 8. ISO7720 Supply Current vs Data Rate (With No Load)**



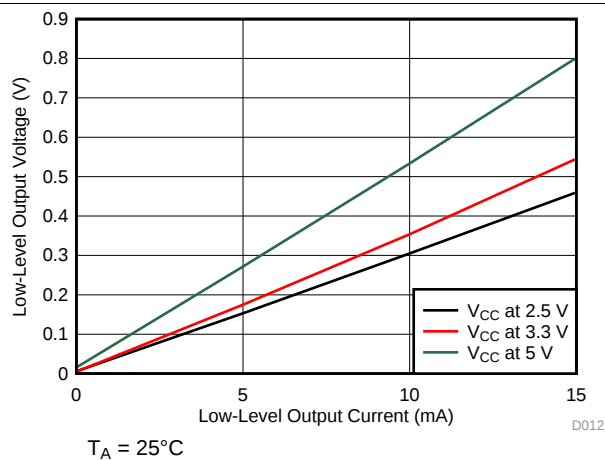
**Figure 9. ISO7721 Supply Current vs Data Rate (With 15-pF Load)**



**Figure 10. ISO7721 Supply Current vs Data Rate (With No Load)**

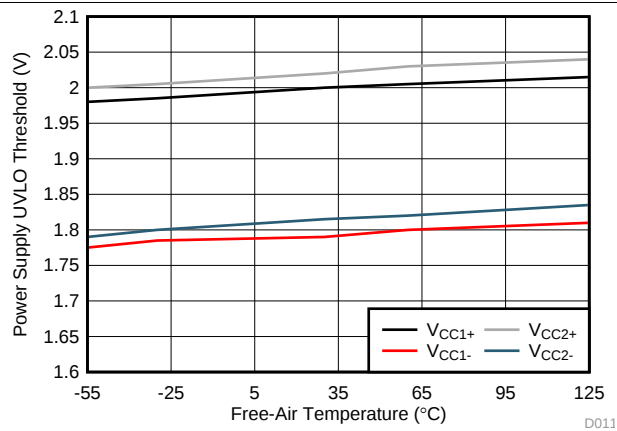


**Figure 11. High-Level Output Voltage vs High-level Output Current**

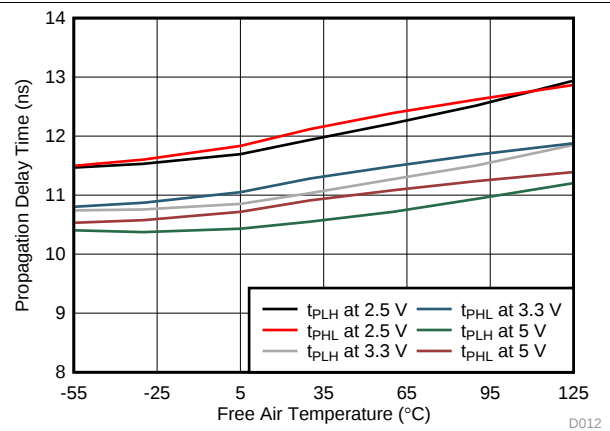


**Figure 12. Low-Level Output Voltage vs Low-Level Output Current**

## Typical Characteristics (continued)

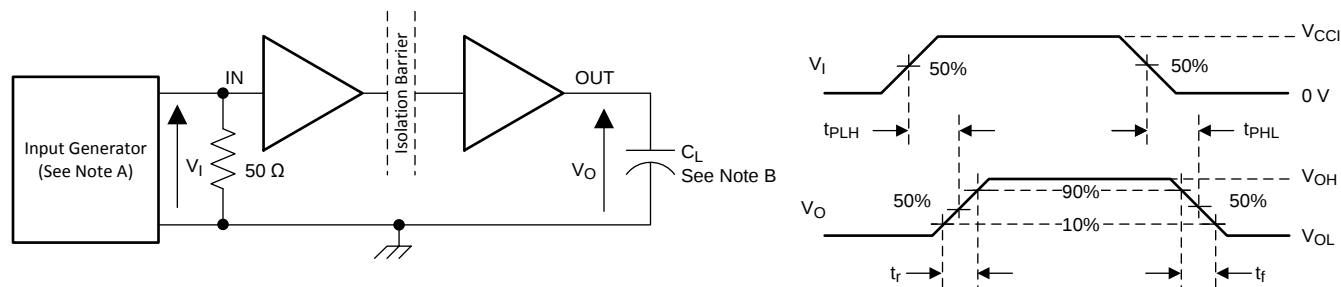


**Figure 13. Power Supply Undervoltage Threshold vs Free-Air Temperature**



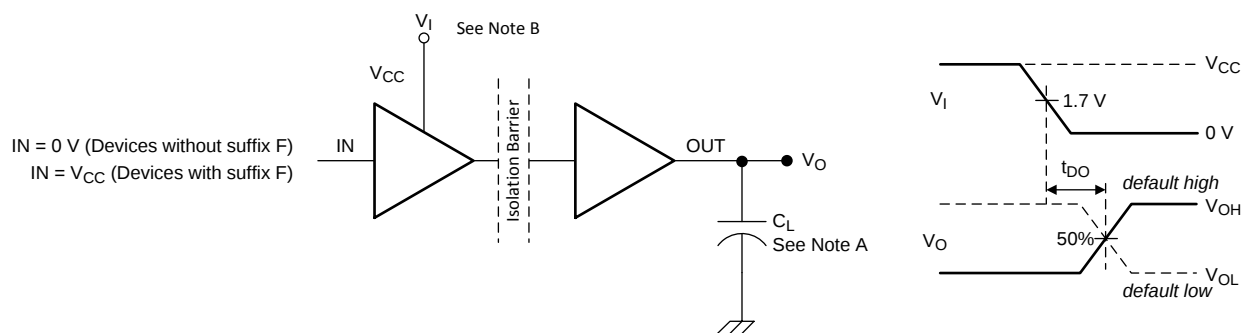
**Figure 14. Propagation Delay Time vs Free-Air Temperature**

## 7 Parameter Measurement Information



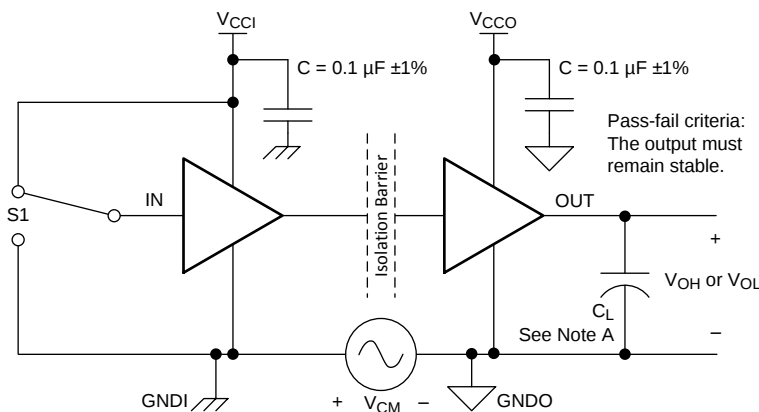
- The input pulse is supplied by a generator having the following characteristics:  $PRR \leq 50$  kHz, 50% duty cycle,  $t_r \leq 3$  ns,  $t_f \leq 3$  ns,  $Z_O = 50 \Omega$ . At the input,  $50 \Omega$  resistor is required to terminate Input Generator signal. It is not needed in actual application.
- $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

**Figure 15. Switching Characteristics Test Circuit and Voltage Waveforms**



- $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .
- Power Supply Ramp Rate = 10 mV/ns

**Figure 16. Default Output Delay Time Test Circuit and Voltage Waveforms**



- $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

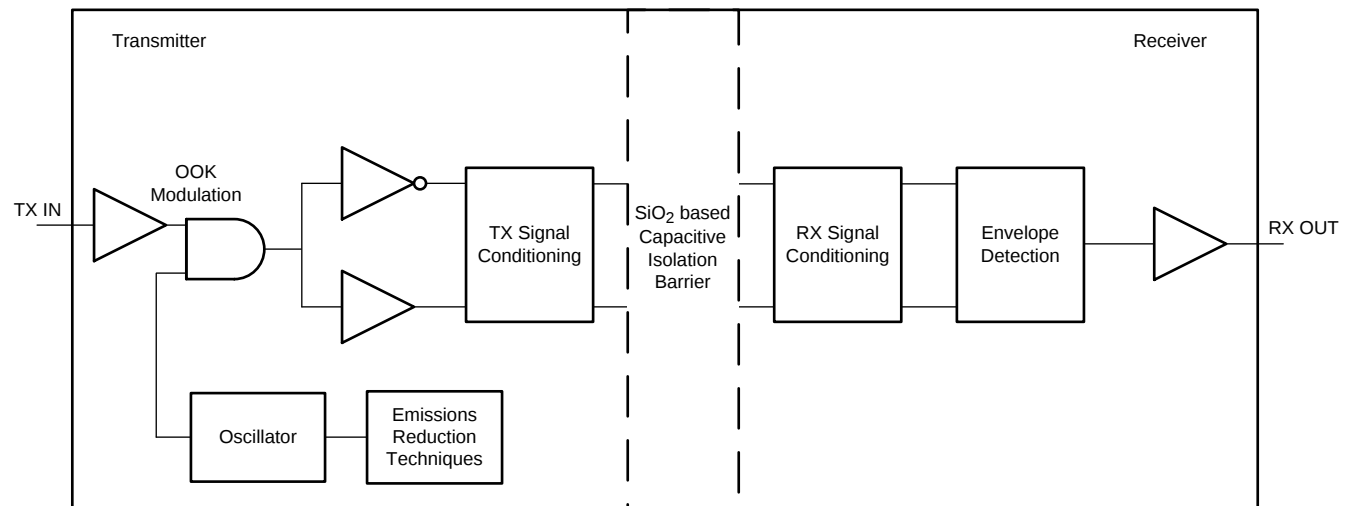
**Figure 17. Common-Mode Transient Immunity Test Circuit**

## 8 Detailed Description

### 8.1 Overview

The ISO772x family of devices has an ON-OFF keying (OOK) modulation scheme to transmit the digital data across a silicon dioxide based isolation barrier. The transmitter sends a high frequency carrier across the barrier to represent one digital state and sends no signal to represent the other digital state. The receiver demodulates the signal after advanced signal conditioning and produces the output through a buffer stage. These devices also incorporate advanced circuit techniques to maximize the CMTI performance and minimize the radiated emissions due the high frequency carrier and IO buffer switching. The conceptual block diagram of a digital capacitive isolator, [Figure 18](#), shows a functional block diagram of a typical channel.

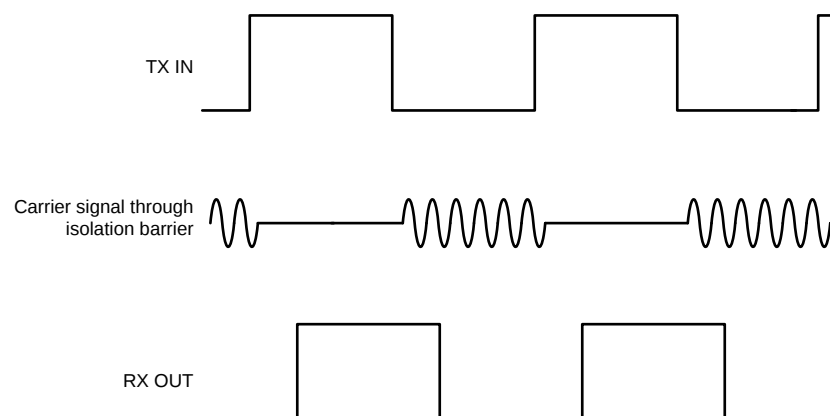
### 8.2 Functional Block Diagram



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**Figure 18. Conceptual Block Diagram of a Digital Capacitive Isolator**

[Figure 19](#) shows a conceptual detail of how the OOK scheme works.



**Figure 19. On-Off Keying (OOK) Based Modulation Scheme**

### 8.3 Feature Description

The ISO772x family of devices is available in two channel configurations and default output state options to enable a variety of application uses. [Table 1](#) lists the device features of the ISO772x devices.

**Table 1. Device Features**

| PART NUMBER | MAXIMUM DATA RATE | CHANNEL DIRECTION    | DEFAULT OUTPUT STATE | PACKAGE | RATED ISOLATION <sup>(1)</sup>               |
|-------------|-------------------|----------------------|----------------------|---------|----------------------------------------------|
| ISO7720     | 100 Mbps          | 2 Forward, 0 Reverse | High                 | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|             |                   |                      |                      | DWV-8   | 5000 V <sub>RMS</sub> / 7071 V <sub>PK</sub> |
|             |                   |                      |                      | D-8     | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7720F    | 100 Mbps          | 2 Forward, 0 Reverse | Low                  | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|             |                   |                      |                      | DWV-8   | 5000 V <sub>RMS</sub> / 7071 V <sub>PK</sub> |
|             |                   |                      |                      | D-8     | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7721     | 100 Mbps          | 1 Forward, 1 Reverse | High                 | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|             |                   |                      |                      | DWV-8   | 5000 V <sub>RMS</sub> / 7071 V <sub>PK</sub> |
|             |                   |                      |                      | D-8     | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |
| ISO7721F    | 100 Mbps          | 1 Forward, 1 Reverse | Low                  | DW-16   | 5000 V <sub>RMS</sub> / 8000 V <sub>PK</sub> |
|             |                   |                      |                      | DWV-8   | 5000 V <sub>RMS</sub> / 7071 V <sub>PK</sub> |
|             |                   |                      |                      | D-8     | 3000 V <sub>RMS</sub> / 4242 V <sub>PK</sub> |

(1) See the [Safety-Related Certifications](#) section for detailed isolation ratings.

#### 8.3.1 Electromagnetic Compatibility (EMC) Considerations

Many applications in harsh industrial environment are sensitive to disturbances such as electrostatic discharge (ESD), electrical fast transient (EFT), surge and electromagnetic emissions. These electromagnetic disturbances are regulated by international standards such as IEC 61000-4-x and CISPR 22. Although system-level performance and reliability depends, to a large extent, on the application board design and layout, the ISO772x family of devices incorporates many chip-level design improvements for overall system robustness. Some of these improvements include:

- Robust ESD protection cells for input and output signal pins and inter-chip bond pads.
- Low-resistance connectivity of ESD cells to supply and ground pins.
- Enhanced performance of high voltage isolation capacitor for better tolerance of ESD, EFT and surge events.
- Bigger on-chip decoupling capacitors to bypass undesirable high energy signals through a low impedance path.
- PMOS and NMOS devices isolated from each other by using guard rings to avoid triggering of parasitic SCRs.
- Reduced common mode currents across the isolation barrier by ensuring purely differential internal operation.

## 8.4 Device Functional Modes

Table 2 lists the functional modes for the ISO772x devices.

Table 2. Function Table<sup>(1)</sup>

| V <sub>CCI</sub> | V <sub>CCO</sub> | INPUT (IN <sub>x</sub> ) <sup>(2)</sup> | OUTPUT (OUT <sub>x</sub> ) | COMMENTS                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|------------------|------------------|-----------------------------------------|----------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| PU               | PU               | H                                       | H                          | Normal Operation:<br>A channel output assumes the logic state of the input.                                                                                                                                                                                                                                                                                                                                                                                       |
|                  |                  | L                                       | L                          |                                                                                                                                                                                                                                                                                                                                                                                                                                                                   |
|                  |                  | Open                                    | Default                    | Default mode: When IN <sub>x</sub> is open, the corresponding channel output goes to the default high logic state. The default is <i>High</i> for ISO772x and <i>Low</i> for ISO772x with F suffix.                                                                                                                                                                                                                                                               |
| PD               | PU               | X                                       | Default                    | Default mode: When V <sub>CCI</sub> is unpowered, a channel output assumes the logic state based on the selected default option. The default is <i>High</i> for ISO772x and <i>Low</i> for ISO772x with F suffix.<br>When V <sub>CCI</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input.<br>When V <sub>CCI</sub> transitions from powered-up to unpowered, channel output assumes the selected default state. |
| X                | PD               | X                                       | Undetermined               | When V <sub>CCO</sub> is unpowered, a channel output is undetermined <sup>(3)</sup> .<br>When V <sub>CCO</sub> transitions from unpowered to powered-up, a channel output assumes the logic state of the input                                                                                                                                                                                                                                                    |

- (1) V<sub>CCI</sub> = Input-side V<sub>CC</sub>; V<sub>CCO</sub> = Output-side V<sub>CC</sub>; PU = Powered up (V<sub>CC</sub> ≥ 2.25 V); PD = Powered down (V<sub>CC</sub> ≤ 1.7 V); X = Irrelevant; H = High level; L = Low level  
(2) A strongly driven input signal can weakly power the floating V<sub>CC</sub> via an internal protection diode and cause undetermined output.  
(3) The outputs are in undetermined state when 1.7 V < V<sub>CCI</sub>, V<sub>CCO</sub> < 2.25 V.

### 8.4.1 Device I/O Schematics

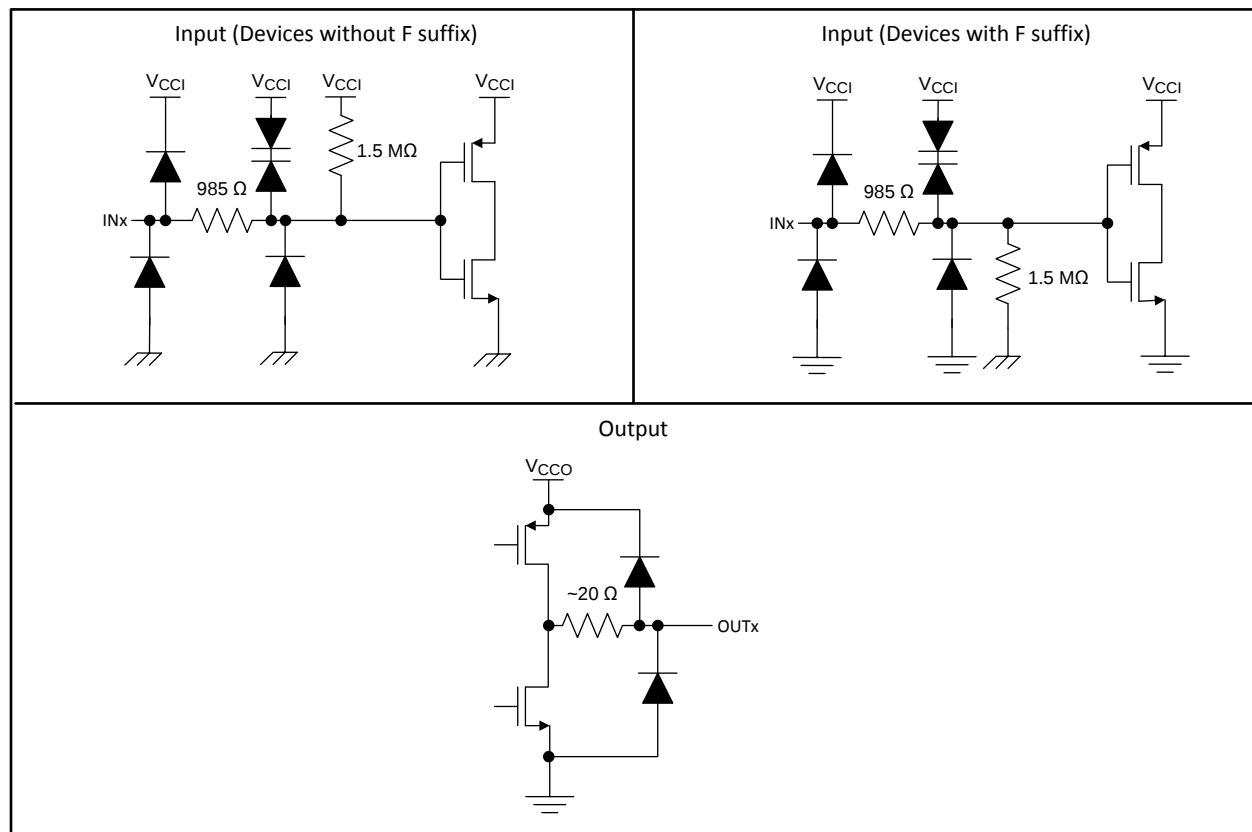


Figure 20. Device I/O Schematics

## 9 Application and Implementation

### NOTE

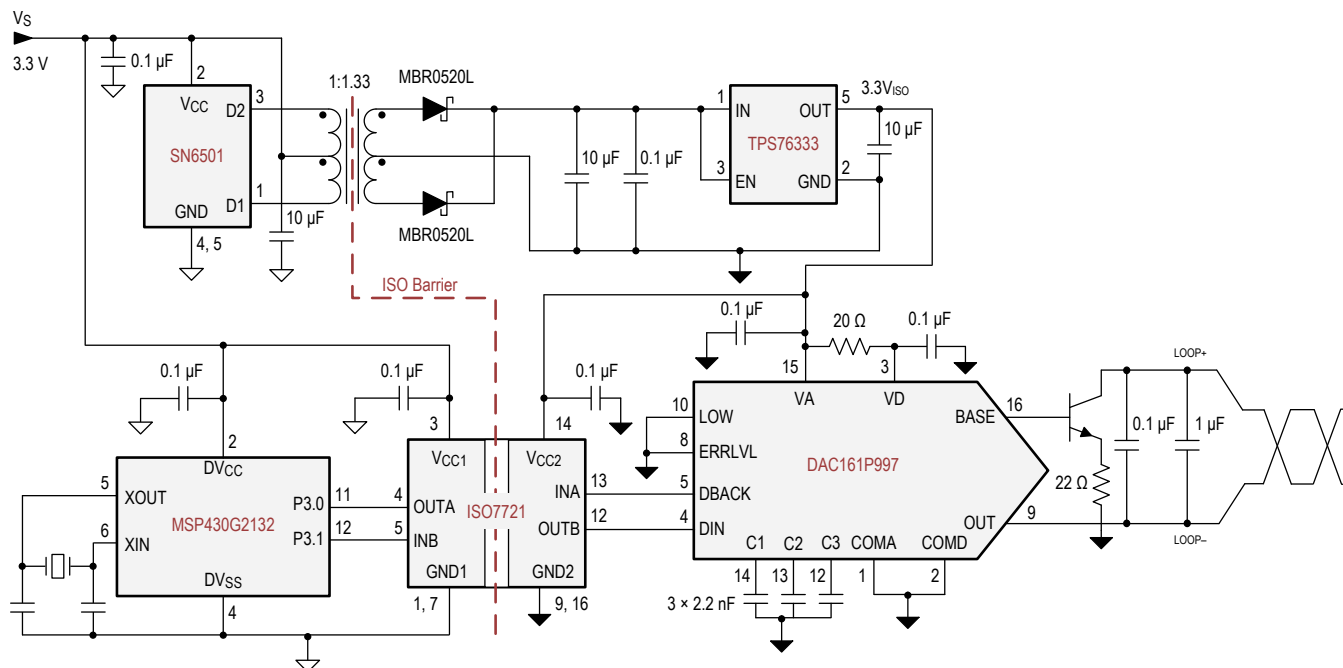
Information in the following applications sections is not part of the TI component specification, and TI does not warrant the accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The ISO772x devices are high-performance, dual-channel digital isolators. The devices use single-ended CMOS-logic switching technology. The supply voltage range is from 2.25 V to 5.5 V for both supplies,  $V_{CC1}$  and  $V_{CC2}$ . When designing with digital isolators, keep in mind that because of the single-ended design structure, digital isolators do not conform to any specific interface standard and are only intended for isolating single-ended CMOS or TTL digital signal lines. The isolator is typically placed between the data controller (that is,  $\mu C$  or UART), and a data converter or a line transceiver, regardless of the interface type or standard.

### 9.2 Typical Application

The ISO7721 device can be used with Texas Instruments' mixed signal microcontroller, digital-to-analog converter, transformer driver, and voltage regulator to create an isolated 4-mA to 20-mA current loop.



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Figure 21. Isolated 4-mA to 20-mA Current Loop

## Typical Application (continued)

### 9.2.1 Design Requirements

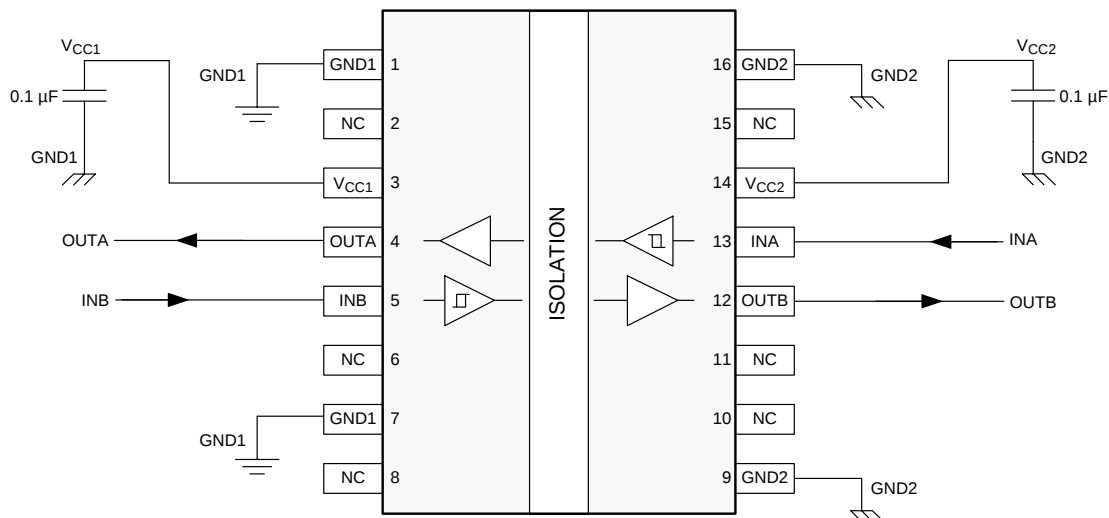
To design with these devices, use the parameters listed in [Table 3](#).

**Table 3. Design Parameters**

| PARAMETER                                       | VALUE           |
|-------------------------------------------------|-----------------|
| Supply voltage, $V_{CC1}$ and $V_{CC2}$         | 2.25 V to 5.5 V |
| Decoupling capacitor between $V_{CC1}$ and GND1 | 0.1 $\mu$ F     |
| Decoupling capacitor from $V_{CC2}$ and GND2    | 0.1 $\mu$ F     |

### 9.2.2 Detailed Design Procedure

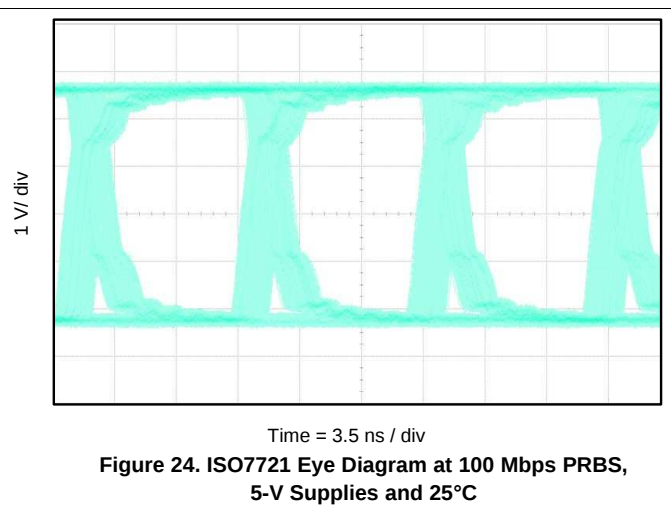
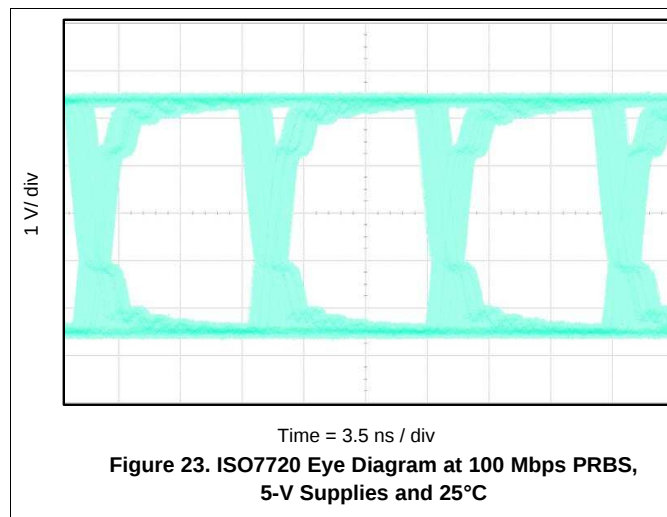
Unlike optocouplers, which require external components to improve performance, provide bias, or limit current, the ISO772x devices only require two external bypass capacitors to operate.



**Figure 22. Typical ISO7721 Circuit Hook-up**

### 9.2.3 Application Curve

The following typical eye diagrams of the ISO772x family of devices indicate low jitter and wide open eye at the maximum data rate of 100 Mbps.



## 10 Power Supply Recommendations

To help ensure reliable operation at data rates and supply voltages, a 0.1- $\mu$ F bypass capacitor is recommended at the input and output supply pins ( $V_{CC1}$  and  $V_{CC2}$ ). The capacitors should be placed as close to the supply pins as possible. If only a single primary-side power supply is available in an application, isolated power can be generated for the secondary-side with the help of a transformer driver such as Texas Instruments' [SN6501](#) or [SN6505A](#). For such applications, detailed power supply design and transformer selection recommendations are available in [SN6501 Transformer Driver for Isolated Power Supplies](#) or [SN6505 Low-Noise 1-A Transformer Drivers for Isolated Power Supplies](#).

## 11 Layout

### 11.1 Layout Guidelines

A minimum of four layers is required to accomplish a low EMI PCB design (see [Figure 25](#)). Layer stacking should be in the following order (top-to-bottom): high-speed signal layer, ground plane, power plane and low-frequency signal layer.

- Routing the high-speed traces on the top layer avoids the use of vias (and the introduction of their inductances) and allows for clean interconnects between the isolator and the transmitter and receiver circuits of the data link.
- Placing a solid ground plane next to the high-speed signal layer establishes controlled impedance for transmission line interconnects and provides an excellent low-inductance path for the return current flow.
- Placing the power plane next to the ground plane creates additional high-frequency bypass capacitance of approximately 100 pF/in<sup>2</sup>.
- Routing the slower speed control signals on the bottom layer allows for greater flexibility as these signal links usually have margin to tolerate discontinuities such as vias.

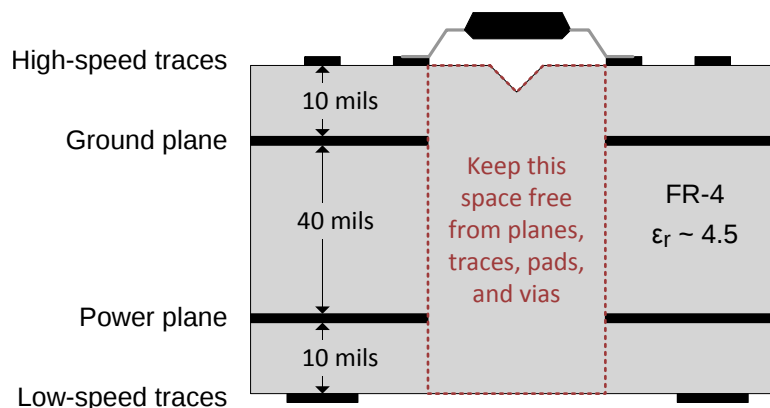
If an additional supply voltage plane or signal layer is needed, add a second power or ground plane system to the stack to keep it symmetrical. This makes the stack mechanically stable and prevents it from warping. Also the power and ground plane of each power system can be placed closer together, thus increasing the high-frequency bypass capacitance significantly.

For detailed layout recommendations, refer to the [Digital Isolator Design Guide](#).

#### 11.1.1 PCB Material

For digital circuit boards operating at less than 150 Mbps, (or rise and fall times greater than 1 ns), and trace lengths of up to 10 inches, use standard FR-4 UL94V-0 printed circuit board. This PCB is preferred over cheaper alternatives because of lower dielectric losses at high frequencies, less moisture absorption, greater strength and stiffness, and the self-extinguishing flammability-characteristics.

### 11.2 Layout Example



**Figure 25. Layout Example**

## 12 器件和文档支持

### 12.1 器件支持

#### 12.1.1 开发支持

有关开发支持，请参阅：

- [隔离式 CAN 灵活数据 \(FD\) 速率中继器参考设计](#)
- [采用双同步采样 ADC 的隔离式 16 通道交流模拟输入模块参考设计](#)
- [具有隔离式 AFE 的多相分流计量参考设计](#)
- [电源隔离型超紧凑模拟输出模块参考设计](#)

### 12.2 文档支持

#### 12.2.1 相关文档

请参阅如下相关文档：

- 德州仪器 (TI)，[《适用于 4mA 至 20mA 回路的 DAC161P997 单线 16 位 DAC》数据表](#)
- 德州仪器 (TI)，[《数字隔离器设计指南》](#)
- 德州仪器 (TI)，[《隔离相关术语》](#)
- 德州仪器 (TI)，[MSP430G2132《混合信号微控制器》数据表](#)
- 德州仪器 (TI)，[《SN6501 用于隔离式电源的变压器驱动器》数据表](#)
- 德州仪器 (TI)，[《TPS76333 低功耗 150mA 低压降线性稳压器》数据表](#)

### 12.3 相关链接

下表列出了快速访问链接。类别包括技术文档、支持与社区资源、工具和软件，以及申请样片或购买产品的快速链接。

表 4. 相关链接

| 器件      | 产品文件夹                 | 立即订购                  | 技术文档                  | 工具与软件                 | 支持和社区                 |
|---------|-----------------------|-----------------------|-----------------------|-----------------------|-----------------------|
| ISO7720 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |
| ISO7721 | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> | <a href="#">请单击此处</a> |

### 12.4 接收文档更新通知

要接收文档更新通知，请导航至 [TI.com.cn](#) 上的器件产品文件夹。单击右上角的 [通知我](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

### 12.5 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [《使用条款》](#)。

**TI E2E™ 在线社区** [TI 的工程师对工程师 \(E2E\) 社区](#)。此社区的创建目的在于促进工程师之间的协作。在 [e2e.ti.com](#) 中，您可以咨询问题、分享知识、拓展思路并与同行工程师一道帮助解决问题。

**设计支持** [TI 参考设计支持](#) 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

### 12.6 商标

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

### 12.7 静电放电警告



ESD 可能会损坏该集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理措施和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

## 12.8 术语表

[SLYZ022](#) — *TI* 术语表。

这份术语表列出并解释术语、缩写和定义。

## **13 机械、封装和可订购信息**

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

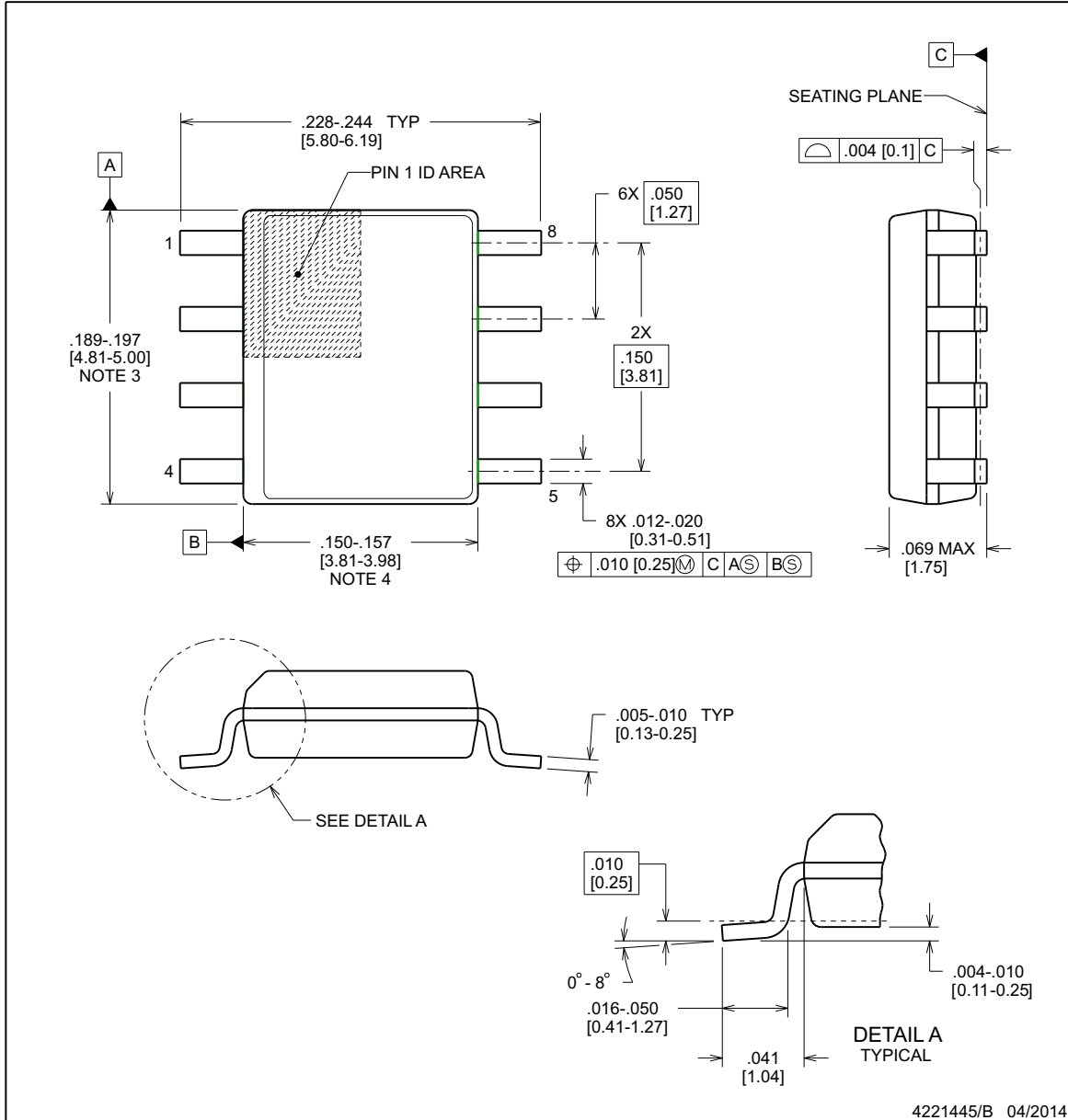


# D0008B

## PACKAGE OUTLINE

SOIC - 1.75 mm max height

SOIC



### NOTES:

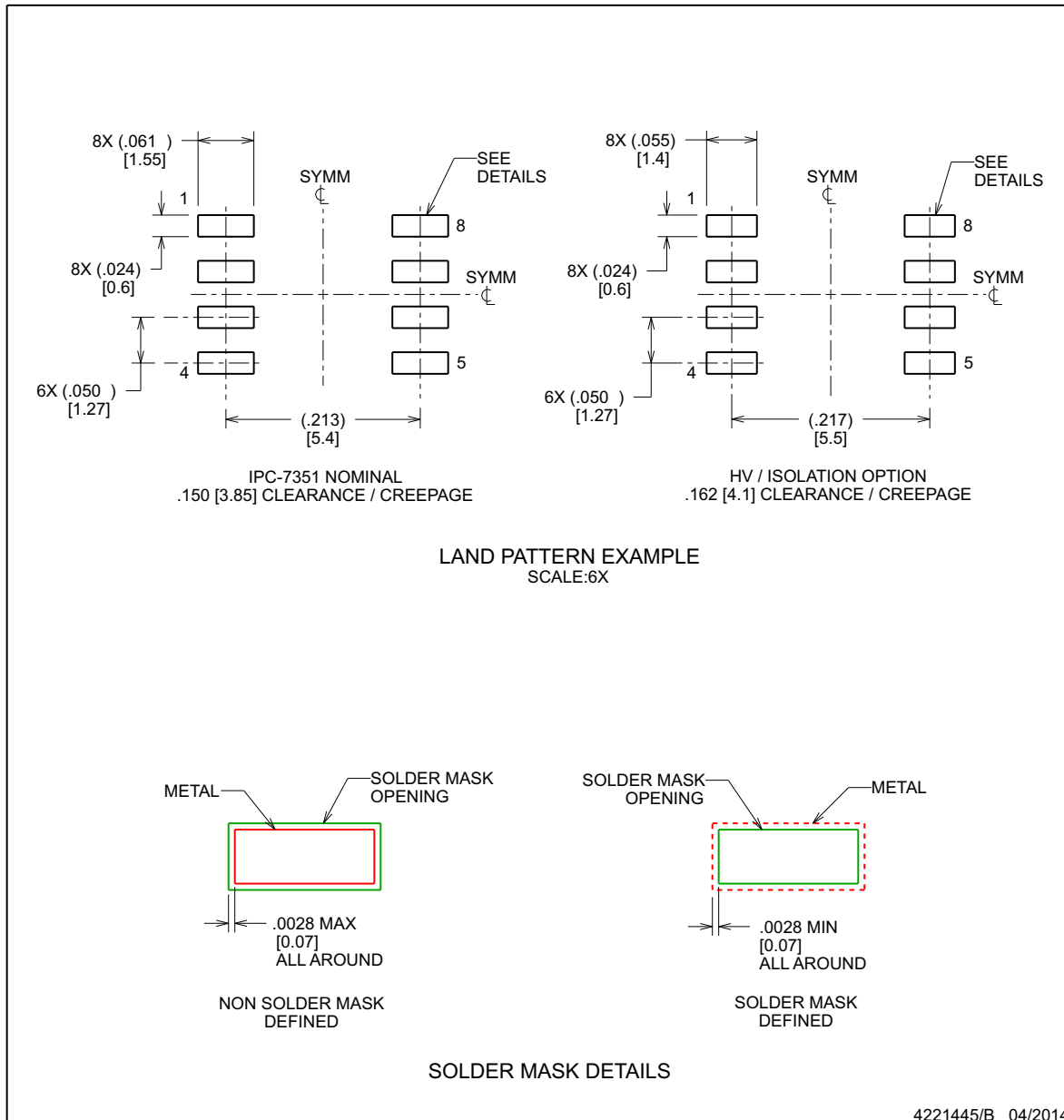
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15], per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

## EXAMPLE BOARD LAYOUT

**D0008B**

**SOIC - 1.75 mm max height**

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

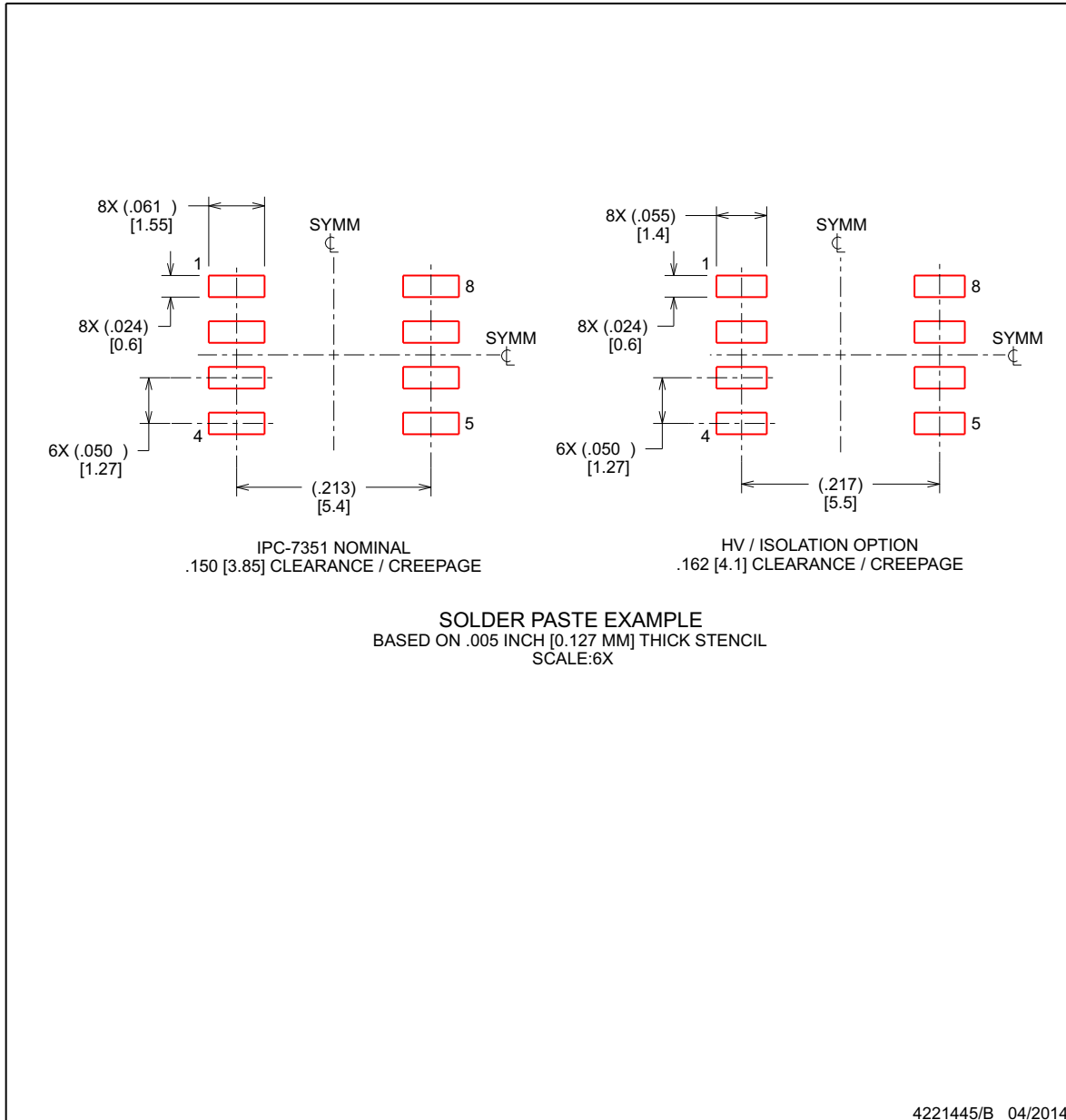
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

**D0008B**

**SOIC - 1.75 mm max height**

SOIC



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| ISO7720D         | ACTIVE        | SOIC         | D                  | 8    | 75             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720                    | <a href="#">Samples</a> |
| ISO7720DR        | ACTIVE        | SOIC         | D                  | 8    | 2500           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720                    | <a href="#">Samples</a> |
| ISO7720DW        | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7720                 | <a href="#">Samples</a> |
| ISO7720DWR       | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7720                 | <a href="#">Samples</a> |
| ISO7720DWV       | ACTIVE        | SOIC         | DWV                | 8    | 64             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720                    | <a href="#">Samples</a> |
| ISO7720DWVR      | ACTIVE        | SOIC         | DWV                | 8    | 1000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720                    | <a href="#">Samples</a> |
| ISO7720FD        | ACTIVE        | SOIC         | D                  | 8    | 75             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720F                   | <a href="#">Samples</a> |
| ISO7720FDR       | ACTIVE        | SOIC         | D                  | 8    | 2500           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720F                   | <a href="#">Samples</a> |
| ISO7720FDW       | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7720F                | <a href="#">Samples</a> |
| ISO7720FDWR      | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7720F                | <a href="#">Samples</a> |
| ISO7720FDWV      | ACTIVE        | SOIC         | DWV                | 8    | 64             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720F                   | <a href="#">Samples</a> |
| ISO7720FDWVR     | ACTIVE        | SOIC         | DWV                | 8    | 1000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7720F                   | <a href="#">Samples</a> |
| ISO7721BDW       | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721B                | <a href="#">Samples</a> |
| ISO7721BDWR      | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721B                | <a href="#">Samples</a> |
| ISO7721D         | ACTIVE        | SOIC         | D                  | 8    | 75             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721                    | <a href="#">Samples</a> |
| ISO7721DR        | ACTIVE        | SOIC         | D                  | 8    | 2500           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721                    | <a href="#">Samples</a> |
| ISO7721DW        | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721                 | <a href="#">Samples</a> |
| ISO7721DWR       | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721                 | <a href="#">Samples</a> |
| ISO7721DWV       | ACTIVE        | SOIC         | DWV                | 8    | 64             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721                    | <a href="#">Samples</a> |
| ISO7721DWVR      | ACTIVE        | SOIC         | DWV                | 8    | 1000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721                    | <a href="#">Samples</a> |

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| ISO7721FBDW      | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721FB               | <a href="#">Samples</a> |
| ISO7721FBDWR     | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721FB               | <a href="#">Samples</a> |
| ISO7721FD        | ACTIVE        | SOIC         | D                  | 8    | 75             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721F                   | <a href="#">Samples</a> |
| ISO7721FDR       | ACTIVE        | SOIC         | D                  | 8    | 2500           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721F                   | <a href="#">Samples</a> |
| ISO7721FDW       | ACTIVE        | SOIC         | DW                 | 16   | 40             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721F                | <a href="#">Samples</a> |
| ISO7721FDWR      | ACTIVE        | SOIC         | DW                 | 16   | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | ISO7721F                | <a href="#">Samples</a> |
| ISO7721FDWV      | ACTIVE        | SOIC         | DWV                | 8    | 64             | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721F                   | <a href="#">Samples</a> |
| ISO7721FDWVR     | ACTIVE        | SOIC         | DWV                | 8    | 1000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -55 to 125   | 7721F                   | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| ISO7720DR    | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7720DWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7720DWVR  | SOIC         | DWV             | 8    | 1000 | 330.0              | 16.4               | 12.05   | 6.15    | 3.3     | 16.0    | 16.0   | Q1            |
| ISO7720FDR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7720FDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7720FDWVR | SOIC         | DWV             | 8    | 1000 | 330.0              | 16.4               | 12.05   | 6.15    | 3.3     | 16.0    | 16.0   | Q1            |
| ISO7721BDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7721BDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7721DR    | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7721DWR   | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7721DWVR  | SOIC         | DWV             | 8    | 1000 | 330.0              | 16.4               | 12.05   | 6.15    | 3.3     | 16.0    | 16.0   | Q1            |
| ISO7721FBDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7721FDR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| ISO7721FDWR  | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| ISO7721FDWVR | SOIC         | DWV             | 8    | 1000 | 330.0              | 16.4               | 12.05   | 6.15    | 3.3     | 16.0    | 16.0   | Q1            |

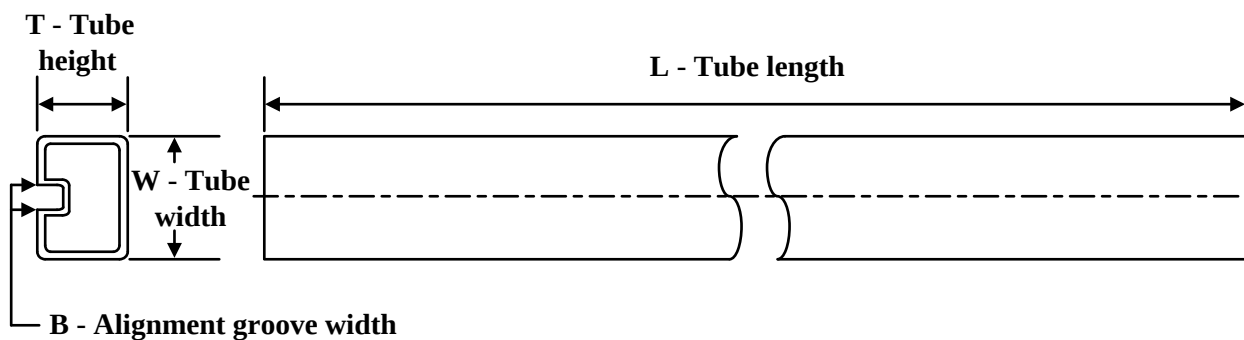
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| ISO7720DR    | SOIC         | D               | 8    | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7720DWR   | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7720DWVR  | SOIC         | DWV             | 8    | 1000 | 350.0       | 350.0      | 43.0        |
| ISO7720FDR   | SOIC         | D               | 8    | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7720FDWR  | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7720FDWVR | SOIC         | DWV             | 8    | 1000 | 350.0       | 350.0      | 43.0        |
| ISO7721BDWR  | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7721BDWR  | SOIC         | DW              | 16   | 2000 | 535.4       | 167.6      | 48.3        |
| ISO7721DR    | SOIC         | D               | 8    | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7721DWR   | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7721DWVR  | SOIC         | DWV             | 8    | 1000 | 350.0       | 350.0      | 43.0        |
| ISO7721FBDWR | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7721FDR   | SOIC         | D               | 8    | 2500 | 350.0       | 350.0      | 43.0        |
| ISO7721FDWR  | SOIC         | DW              | 16   | 2000 | 350.0       | 350.0      | 43.0        |
| ISO7721FDWVR | SOIC         | DWV             | 8    | 1000 | 350.0       | 350.0      | 43.0        |

## TUBE



\*All dimensions are nominal

| Device      | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| ISO7720D    | D            | SOIC         | 8    | 75  | 505.46 | 6.76   | 3810   | 4      |
| ISO7720DW   | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7720DWV  | DWV          | SOIC         | 8    | 64  | 505.46 | 13.94  | 4826   | 6.6    |
| ISO7720FD   | D            | SOIC         | 8    | 75  | 505.46 | 6.76   | 3810   | 4      |
| ISO7720FDW  | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7720FDWV | DWV          | SOIC         | 8    | 64  | 505.46 | 13.94  | 4826   | 6.6    |
| ISO7721BDW  | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7721D    | D            | SOIC         | 8    | 75  | 505.46 | 6.76   | 3810   | 4      |
| ISO7721DW   | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7721DWV  | DWV          | SOIC         | 8    | 64  | 505.46 | 13.94  | 4826   | 6.6    |
| ISO7721FBDW | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7721FD   | D            | SOIC         | 8    | 75  | 505.46 | 6.76   | 3810   | 4      |
| ISO7721FDW  | DW           | SOIC         | 16   | 40  | 506.98 | 12.7   | 4826   | 6.6    |
| ISO7721FDWV | DWV          | SOIC         | 8    | 64  | 505.46 | 13.94  | 4826   | 6.6    |

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